MSP430x13x, MSP430x14x, MSP430x14x1 MIXED SIGNAL MICROCONTROLLER

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- Low Supply-Voltage Range, 1.8 V . . . 3.6 V
- Ultralow-Power Consumption:
 - Active Mode: 280 μ A at 1 MHz, 2.2V
 - Standby Mode: 1.6 μA
 - Off Mode (RAM Retention): 0.1 μA
- Five Power-Saving Modes
- Wake-Up From Standby Mode in less than 6 μs
- 16-Bit RISC Architecture,
 125-ns Instruction Cycle Time
- 12-Bit A/D Converter With Internal Reference, Sample-and-Hold and Autoscan Feature
- 16-Bit Timer_B With Seven
 Capture/Compare-With-Shadow Registers
- 16-Bit Timer_A With Three Capture/Compare Registers
- On-Chip Comparator
- Serial Onboard Programming, No External Programming Voltage Needed Programmable Code Protection by Security Fuse

- Serial Communication Interface (USART), Functions as Asynchronous UART or Synchronous SPI Interface
 - Two USARTs (USART0, USART1) MSP430x14x(1) Devices
 - One USART (USART0) MSP430x13x Devices
- Family Members Include:
 - MSP430F133:

8KB+256B Flash Memory, 256B RAM

MSP430F135:

16KB+256B Flash Memory, 512B RAM

- MSP430F147, MSP430F1471†:
 32KB+256B Flash Memory,
 1KB RAM
- MSP430F148, MSP430F1481†:
 48KB+256B Flash Memory,
 2KB RAM
- MSP430F149, MSP430F1491†:
 60KB+256B Flash Memory,
 2KB RAM
- Available in 64-Pin Quad Flat Pack (QFP) and 64-pin QFN
- For Complete Module Descriptions, See the MSP430x1xx Family User's Guide, Literature Number SLAU049

description

The Texas Instruments MSP430 family of ultralow-power microcontrollers consist of several devices featuring different sets of peripherals targeted for various applications. The architecture, combined with five low power modes is optimized to achieve extended battery life in portable measurement applications. The device features a powerful 16-bit RISC CPU, 16-bit registers, and constant generators that attribute to maximum code efficiency. The digitally controlled oscillator (DCO) allows wake-up from low-power modes to active mode in less than 6 µs.

The MSP430x13x and the MSP430x14x(1) series are microcontroller configurations with two built-in 16-bit timers, a fast 12-bit A/D converter (not implemented on the MSP430F14x1 devices), one or two universal serial synchronous/asynchronous communication interfaces (USART), and 48 I/O pins.

Typical applications include sensor systems that capture analog signals, convert them to digital values, and process and transmit the data to a host system. The timers make the configurations ideal for industrial control applications such as ripple counters, digital motor control, EE-meters, hand-held meters, etc. The hardware multiplier enhances the performance and offers a broad code and hardware-compatible family solution.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

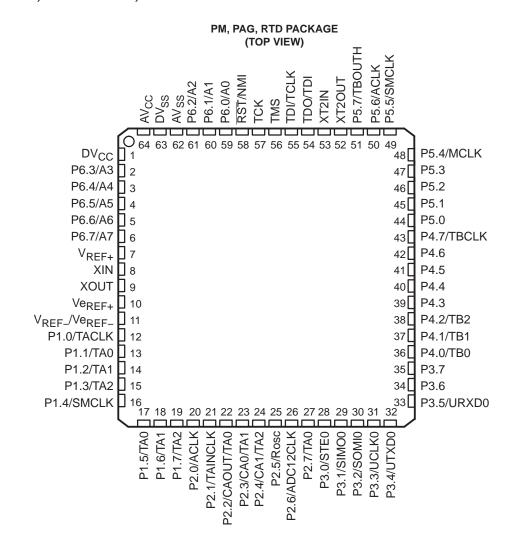


[†] The MSP430F14x1 devices are identical to the MSP430F14x devices with the exception that the ADC12 module is not implemented.

AVAILABLE OPTIONS

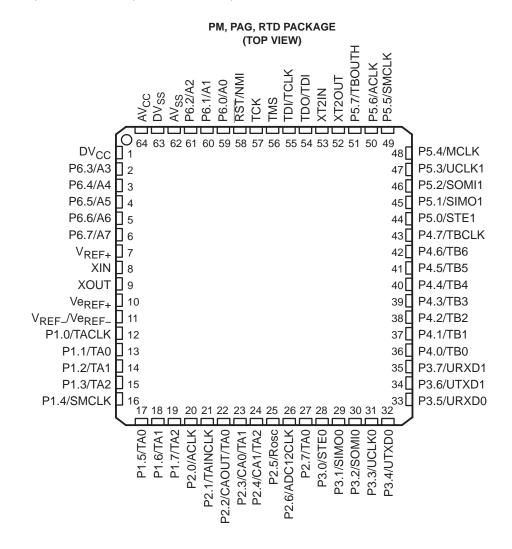
	PACKAGED DEVICES							
TA	PLASTIC 64-PIN QFP (PM)	PLASTIC 64-PIN QFP (PAG)	PLASTIC 64-PIN QFN (RTD)					
-40°C to 85°C	MSP430F133IPM MSP430F135IPM MSP430F147IPM MSP430F1471IPM MSP430F148IPM MSP430F1481IPM MSP430F149IPM MSP430F1491IPM	MSP430F133IPAG MSP430F135IPAG MSP430F147IPAG MSP430F148IPAG MSP430F149IPAG	MSP430F133IRTD MSP430F135IRTD MSP430F147IRTD MSP430F147IRTD MSP430F148IRTD MSP430F148IIRTD MSP430F149IRTD MSP430F149IRTD					

pin designation, MSP430F133, MSP430F135

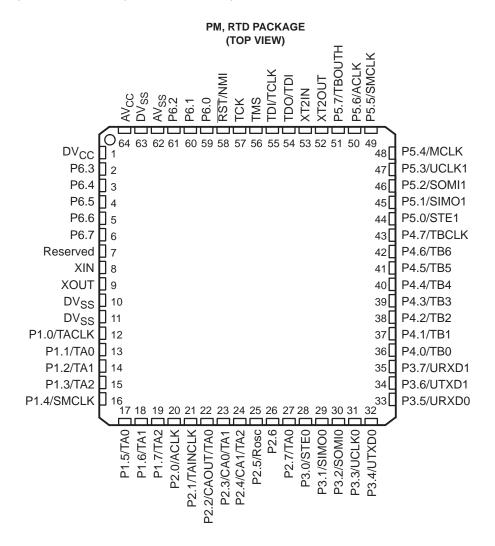




pin designation, MSP430F147, MSP430F148, MSP430F149

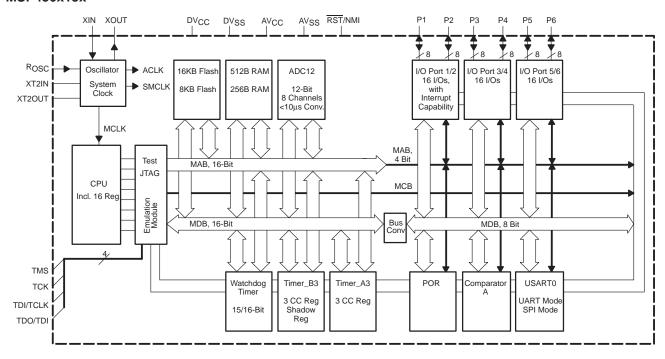


pin designation, MSP430F1471, MSP430F1481, MSP430F1491

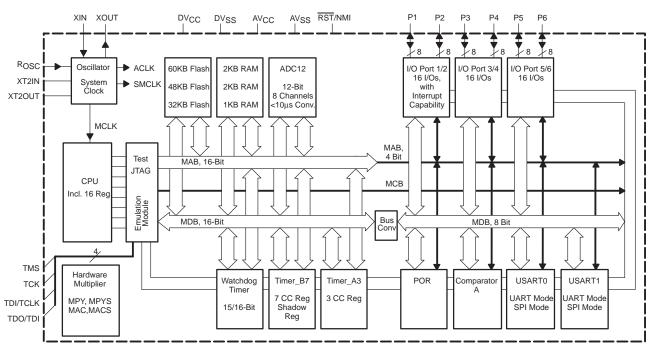


functional block diagrams

MSP430x13x



MSP430x14x

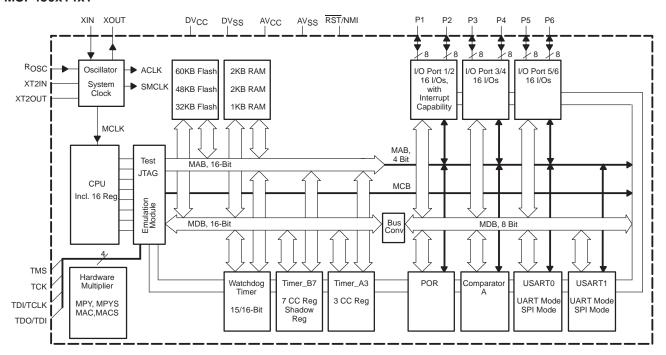


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functional block diagrams (continued)

MSP430x14x1





Terminal Functions

MSP430x13x, MSP430x14x

TERMINAL I/O		1/0	DESCRIPTION
AVCC	64		Analog supply voltage, positive terminal. Supplies the analog portion of the analog-to-digital converter.
AVSS	62		Analog supply voltage, negative terminal. Supplies the analog portion of the analog-to-digital converter.
DVCC	1		Digital supply voltage, positive terminal. Supplies all digital parts.
DV _{SS}	63		Digital supply voltage, negative terminal. Supplies all digital parts.
P1.0/TACLK	12	I/O	General-purpose digital I/O pin/Timer_A, clock signal TACLK input
P1.1/TA0	13	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI0A input, compare: Out0 output/BSL transmit
P1.2/TA1	14	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI1A input, compare: Out1 output
P1.3/TA2	15	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI2A input, compare: Out2 output
P1.4/SMCLK	16	I/O	General-purpose digital I/O pin/SMCLK signal output
P1.5/TA0	17	I/O	General-purpose digital I/O pin/Timer_A, compare: Out0 output
P1.6/TA1	18	I/O	General-purpose digital I/O pin/Timer_A, compare: Out1 output
P1.7/TA2	19	I/O	General-purpose digital I/O pin/Timer_A, compare: Out2 output/
P2.0/ACLK	20	I/O	General-purpose digital I/O pin/ACLK output
P2.1/TAINCLK	21	I/O	General-purpose digital I/O pin/Timer_A, clock signal at INCLK
P2.2/CAOUT/TA0	22	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI0B input/Comparator_A output/BSL receive
P2.3/CA0/TA1	23	I/O	General-purpose digital I/O pin/Timer_A, compare: Out1 output/Comparator_A input
P2.4/CA1/TA2	24	I/O	General-purpose digital I/O pin/Timer_A, compare: Out2 output/Comparator_A input
P2.5/Rosc	25	I/O	General-purpose digital I/O pin/input for external resistor defining the DCO nominal frequency
P2.6/ADC12CLK	26	I/O	General-purpose digital I/O pin/conversion clock – 12-bit ADC
P2.7/TA0	27	I/O	General-purpose digital I/O pin/Timer_A, compare: Out0 output
P3.0/STE0	28	I/O	General-purpose digital I/O pin/slave transmit enable – USART0/SPI mode
P3.1/SIMO0	29	I/O	General-purpose digital I/O pin/slave in/master out of USART0/SPI mode
P3.2/SOMI0	30	I/O	General-purpose digital I/O pin/slave out/master in of USART0/SPI mode
P3.3/UCLK0	31	I/O	General-purpose digital I/O/USART0 clock: external input – UART or SPI mode, output – SPI mode
P3.4/UTXD0	32	I/O	General-purpose digital I/O pin/transmit data out – USART0/UART mode
P3.5/URXD0	33	I/O	General-purpose digital I/O pin/receive data in – USART0/UART mode
P3.6/UTXD1 [†]	34	I/O	General-purpose digital I/O pin/transmit data out – USART1/UART mode
P3.7/URXD1 [†]	35	I/O	General-purpose digital I/O pin/receive data in – USART1/UART mode
P4.0/TB0	36	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI0A or CCI0B input, compare: Out0 output
P4.1/TB1	37	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI1A or CCI1B input, compare: Out1 output
P4.2/TB2	38	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI2A or CCI2B input, compare: Out2 output
P4.3/TB3†	39	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI3A or CCI3B input, compare: Out3 output
P4.4/TB4 [†]	40	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI4A or CCI4B input, compare: Out4 output
P4.5/TB5 [†]	41	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI5A or CCI5B input, compare: Out5 output
P4.6/TB6 [†]	42	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI6A or CCI6B input, compare: Out6 output
P4.7/TBCLK	43	I/O	General-purpose digital I/O pin/Timer_B, clock signal TBCLK input
P5.0/STE1 [†]	44	I/O	General-purpose digital I/O pin/slave transmit enable – USART1/SPI mode
P5.1/SIMO1 [†]	45	I/O	General-purpose digital I/O pin/slave in/master out of USART1/SPI mode
P5.2/SOMI1 [†]	46	I/O	General-purpose digital I/O pin/slave out/master in of USART1/SPI mode
P5.3/UCLK1 [†]	47	I/O	General-purpose digital I/O pin/USART1 clock: external input – UART or SPI mode, output – SPI mode
P5.4/MCLK	48	I/O	General-purpose digital I/O pin/main system clock MCLK output
P5.5/SMCLK	49	I/O	General-purpose digital I/O pin/submain system clock SMCLK output

^{† 14}x devices only



Terminal Functions (Continued)

MSP430x13x, MSP430x14x (continued)

TERMINAL		1/0	DECODIFICAL			
NAME	NO.	1/0	DESCRIPTION			
P5.6/ACLK	50	I/O	General-purpose digital I/O pin/auxiliary clock ACLK output			
P5.7/TBOUTH	51	I/O	General-purpose digital I/O pin/switch all PWM digital output ports to high impedance – Timer_B7: TB0 to TB6			
P6.0/A0	59	I/O	General-purpose digital I/O pin/analog input a0 – 12-bit ADC			
P6.1/A1	60	I/O	General-purpose digital I/O pin/analog input a1 – 12-bit ADC			
P6.2/A2	61	I/O	General-purpose digital I/O pin/analog input a2 – 12-bit ADC			
P6.3/A3	2	I/O	General-purpose digital I/O pin/analog input a3 – 12-bit ADC			
P6.4/A4	3	I/O	General-purpose digital I/O pin/analog input a4 – 12-bit ADC			
P6.5/A5	4	I/O	General-purpose digital I/O pin/analog input a5 – 12-bit ADC			
P6.6/A6	5	I/O	General-purpose digital I/O pin/analog input a6 – 12-bit ADC			
P6.7/A7	6	I/O	General-purpose digital I/O pin/analog input a7 – 12-bit ADC			
RST/NMI	58	I	Reset input, nonmaskable interrupt input port, or bootstrap loader start (in Flash devices).			
TCK	57	I	Test clock. TCK is the clock input port for device programming test and bootstrap loader start (in Flash devices).			
TDI/TCLK	55	I	Test data input or test clock input. The device protection fuse is connected to TDI/TCLK.			
TDO/TDI	54	I/O	Test data output port. TDO/TDI data output or programming data input terminal			
TMS	56	- 1	Test mode select. TMS is used as an input port for device programming and test.			
Ve _{REF+}	10	- 1	Input for an external reference voltage to the ADC			
V _{REF+}	7	0	Output of positive terminal of the reference voltage in the ADC			
V _{REF} _/Ve _{REF} _	11	I	Negative terminal for the ADC's reference voltage for both sources, the internal reference voltage, or an external applied reference voltage			
XIN	8	- 1	Input port for crystal oscillator XT1. Standard or watch crystals can be connected.			
XOUT	9	0	Output terminal of crystal oscillator XT1			
XT2IN	53	I	Input port for crystal oscillator XT2. Only standard crystals can be connected.			
XT2OUT	52	0	Output terminal of crystal oscillator XT2			
QFN Pad	NA	NA	QFN package pad connection to DV _{SS} recommended.			



Terminal Functions

MSP430x14x1

TERMINAL		1/0	DESCRIPTION	
NAME	NO.			
AVCC	64		Analog supply voltage, positive terminal.	
AVSS	62		Analog supply voltage, negative terminal.	
DV _{CC}	1		Digital supply voltage, positive terminal. Supplies all digital parts.	
DV _{SS}	63		Digital supply voltage, negative terminal. Supplies all digital parts.	
P1.0/TACLK	12	I/O	General-purpose digital I/O pin/Timer_A, clock signal TACLK input	
P1.1/TA0	13	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI0A input, compare: Out0 output/BSL transmit	
P1.2/TA1	14	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI1A input, compare: Out1 output	
P1.3/TA2	15	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI2A input, compare: Out2 output	
P1.4/SMCLK	16	I/O	General-purpose digital I/O pin/SMCLK signal output	
P1.5/TA0	17	I/O	General-purpose digital I/O pin/Timer_A, compare: Out0 output	
P1.6/TA1	18	I/O	General-purpose digital I/O pin/Timer_A, compare: Out1 output	
P1.7/TA2	19	I/O	General-purpose digital I/O pin/Timer_A, compare: Out2 output	
P2.0/ACLK	20	I/O	General-purpose digital I/O pin/ACLK output	
P2.1/TAINCLK	21	I/O	General-purpose digital I/O pin/Timer_A, clock signal at INCLK	
P2.2/CAOUT/TA0	22	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI0B input/Comparator_A output/BSL receive	
P2.3/CA0/TA1	23	I/O	General-purpose digital I/O pin/Timer_A, compare: Out1 output/Comparator_A input	
P2.4/CA1/TA2	24	I/O	General-purpose digital I/O pin/Timer_A, compare: Out2 output/Comparator_A input	
P2.5/ROSC	25	I/O	General-purpose digital I/O pin/input for external resistor defining the DCO nominal frequency	
P2.6	26	I/O	General-purpose digital I/O pin	
P2.7/TA0	27	I/O	General-purpose digital I/O pin/Timer_A, compare: Out0 output	
P3.0/STE0	28	I/O	General-purpose digital I/O pin/slave transmit enable – USART0/SPI mode	
P3.1/SIMO0	29	I/O	General-purpose digital I/O pin/slave in/master out of USART0/SPI mode	
P3.2/SOMI0	30	I/O	General-purpose digital I/O pin/slave out/master in of USART0/SPI mode	
P3.3/UCLK0	31	I/O	General-purpose digital I/O/USART0 clock: external input – UART or SPI mode, output – SPI mode	
P3.4/UTXD0	32	I/O	General-purpose digital I/O pin/transmit data out – USART0/UART mode	
P3.5/URXD0	33	I/O	General-purpose digital I/O pin/receive data in – USART0/UART mode	
P3.6/UTXD1	34	I/O	General-purpose digital I/O pin/transmit data out – USART1/UART mode	
P3.7/URXD1	35	I/O	General-purpose digital I/O pin/receive data in – USART1/UART mode	
P4.0/TB0	36	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI0A or CCI0B input, compare: Out0 output	
P4.1/TB1	37	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI1A or CCI1B input, compare: Out1 output	
P4.2/TB2	38	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI2A or CCI2B input, compare: Out2 output	
P4.3/TB3	39	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI3A or CCI3B input, compare: Out3 output	
P4.4/TB4	40	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI4A or CCI4B input, compare: Out4 output	
P4.5/TB5	41	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI5A or CCI5B input, compare: Out5 output	
P4.6/TB6	42	I/O	General-purpose digital I/O pin/Timer_B, capture: CCI6A or CCI6B input, compare: Out6 output	
P4.7/TBCLK	43	I/O	General-purpose digital I/O pin/Timer_B, clock signal TBCLK input	
P5.0/STE1	44	I/O	General-purpose digital I/O pin/slave transmit enable – USART1/SPI mode	
P5.1/SIMO1	45	I/O	General-purpose digital I/O pin/slave in/master out of USART1/SPI mode	
P5.2/SOMI1	46	I/O	General-purpose digital I/O pin/slave out/master in of USART1/SPI mode	
P5.3/UCLK1	47	I/O	General-purpose digital I/O pin/USART1 clock: external input – UART or SPI mode, output – SPI mode	
P5.4/MCLK	48	I/O	General-purpose digital I/O pin/main system clock MCLK output	
P5.5/SMCLK	49	I/O	General-purpose digital I/O pin/submain system clock SMCLK output	



Terminal Functions (Continued)

MSP430x14x1 (continued)

TERMINAL						
NAME	NO.	1/0	DESCRIPTION			
P5.6/ACLK	50	I/O	General-purpose digital I/O pin/auxiliary clock ACLK output			
P5.7/TBOUTH	51	I/O	General-purpose digital I/O pin/switch all PWM digital output ports to high impedance – Timer_B7: TB0 to TB6			
P6.0	59	I/O	General-purpose digital I/O pin			
P6.1	60	I/O	General-purpose digital I/O pin			
P6.2	61	I/O	General-purpose digital I/O pin			
P6.3	2	I/O	General-purpose digital I/O pin			
P6.4	3	I/O	General-purpose digital I/O pin			
P6.5	4	I/O	General-purpose digital I/O pin			
P6.6	5	I/O	General-purpose digital I/O pin			
P6.7	6	I/O	General-purpose digital I/O pin			
RST/NMI	58	I	Reset input, nonmaskable interrupt input port, or bootstrap loader start (in Flash devices).			
TCK	57	I	Test clock. TCK is the clock input port for device programming test and bootstrap loader start (in Flash devices).			
TDI/TCLK	55	I	Test data input or test clock input. The device protection fuse is connected to TDI/TCLK.			
TDO/TDI	54	I/O	Test data output port. TDO/TDI data output or programming data input terminal			
TMS	56	- 1	Test mode select. TMS is used as an input port for device programming and test.			
DV _{SS}	10	- 1	Connect to DV _{SS}			
Reserved	7		Reserved, do not connect externally			
DVSS	11	- 1	Connect to DVSS			
XIN	8	I	Input port for crystal oscillator XT1. Standard or watch crystals can be connected.			
XOUT	9	0	Output terminal of crystal oscillator XT1			
XT2IN	53	I	Input port for crystal oscillator XT2. Only standard crystals can be connected.			
XT2OUT	52	0	Output terminal of crystal oscillator XT2			
QFN Pad	NA	NA	QFN package pad connection to DV _{SS} recommended.			

short-form description

CPU

The MSP430 CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock.

Four of the registers, R0 to R3, are dedicated as program counter, stack pointer, status register, and constant generator respectively. The remaining registers are general-purpose registers.

Peripherals are connected to the CPU using data, address, and control buses, and can be handled with all instructions.

instruction set

The instruction set consists of 51 instructions with three formats and seven address modes. Each instruction can operate on word and byte data. Table 1 shows examples of the three types of instruction formats; the address modes are listed in Table 2.

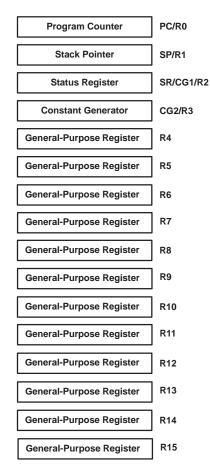


Table 1. Instruction Word Formats

Dual operands, source-destination	e.g. ADD R4,R5	R4 + R5> R5
Single operands, destination only	e.g. CALL R8	PC>(TOS), R8> PC
Relative jump, un/conditional	e.g. JNE	Jump-on-equal bit = 0

Table 2. Address Mode Descriptions

ADDRESS MODE S D		SYNTAX	EXAMPLE	OPERATION		
Register	Register • •		MOV Rs,Rd	MOV R10,R11	R10> R11	
Indexed	• •		MOV X(Rn),Y(Rm)	MOV 2(R5),6(R6)	M(2+R5)> M(6+R6)	
Symbolic (PC relative)	ymbolic (PC relative)		MOV EDE,TONI		M(EDE)> M(TONI)	
Absolute	•	•	MOV &MEM,&TCDAT		M(MEM)> M(TCDAT)	
Indirect	•		MOV @Rn,Y(Rm)	MOV @R10,Tab(R6)	M(R10)> M(Tab+R6)	
Indirect autoincrement			MOV @Rn+,Rm	MOV @R10+,R11	M(R10)> R11 R10 + 2> R10	
Immediate	•		MOV #X,TONI	MOV #45,TONI	#45> M(TONI)	

NOTE: S = source D = destination



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operating modes

The MSP430 has one active mode and five software selectable low-power modes of operation. An interrupt event can wake up the device from any of the five low-power modes, service the request and restore back to the low-power mode on return from the interrupt program.

The following six operating modes can be configured by software:

- Active mode AM;
 - All clocks are active
- Low-power mode 0 (LPM0);
 - CPU is disabled ACLK and SMCLK remain active. MCLK is disabled
- Low-power mode 1 (LPM1);
 - CPU is disabled
 ACLK and SMCLK remain active. MCLK is disabled
 DCO's dc-generator is disabled if DCO not used in active mode
- Low-power mode 2 (LPM2);
 - CPU is disabled
 MCLK and SMCLK are disabled
 DCO's dc-generator remains enabled
 ACLK remains active
- Low-power mode 3 (LPM3);
 - CPU is disabled
 MCLK and SMCLK are disabled
 DCO's dc-generator is disabled
 ACLK remains active
- Low-power mode 4 (LPM4);
 - CPU is disabled
 ACLK is disabled
 MCLK and SMCLK are disabled
 DCO's dc-generator is disabled
 Crystal oscillator is stopped



interrupt vector addresses

The interrupt vectors and the power-up starting address are located in the address range 0FFFh – 0FFE0h. The vector contains the 16-bit address of the appropriate interrupt-handler instruction sequence.

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
Power-up External Reset Watchdog Flash memory	WDTIFG KEYV (see Note 1)	Reset	0FFFEh	15, highest
NMI Oscillator Fault Flash memory access violation	NMIIFG (see Notes 1 & 4) OFIFG (see Notes 1 & 4) ACCVIFG (see Notes 1 & 4)	(Non)maskable (Non)maskable (Non)maskable	0FFFCh	14
Timer_B7 (see Note 5)	TBCCR0 CCIFG (see Note 2)	Maskable	0FFFAh	13
Timer_B7 (see Note 5)	TBCCR1 to 6 CCIFGs, TBIFG (see Notes 1 & 2)	Maskable	0FFF8h	12
Comparator_A	CAIFG	Maskable	0FFF6h	11
Watchdog timer	WDTIFG	Maskable	0FFF4h	10
USART0 receive	URXIFG0	Maskable	0FFF2h	9
USART0 transmit	UTXIFG0	Maskable	0FFF0h	8
ADC12 (see Note 6)	ADC12IFG (see Notes 1 & 2)	Maskable	0FFEEh	7
Timer_A3	TACCR0 CCIFG (see Note 2)	Maskable	0FFECh	6
Timer_A3	TACCR1 CCIFG, TACCR2 CCIFG, TAIFG (see Notes 1 & 2)	Maskable	0FFEAh	5
I/O port P1 (eight flags)	P1IFG.0 to P1IFG.7 (see Notes 1 & 2)	Maskable	0FFE8h	4
USART1 receive	URXIFG1	Maskable	0FFE6h	3
USART1 transmit	UTXIFG1		0FFE4h	2
I/O port P2 (eight flags)	P2IFG.0 to P2IFG.7 (see Notes 1 & 2)	Maskable	0FFE2h	1
			0FFE0h	0, lowest

NOTES: 1. Multiple source flags

- 2. Interrupt flags are located in the module.
- 3. Nonmaskable: neither the individual nor the general interrupt-enable bit will disable an interrupt event.
- 4. (Non)maskable: the individual interrupt-enable bit can disable an interrupt event, but the general-interrupt enable can not disable it
- 5. Timer_B7 in MSP430x14x(1) family has 7 CCRs; Timer_B3 in MSP430x13x family has 3 CCRs. In Timer_B3 there are only interrupt flags TBCCR0, 1, and 2 CCIFGs and the interrupt-enable bits TBCCTL0, 1, and 2 CCIEs.
- 6. ADC12 is not implemented on the 14x1 devices.



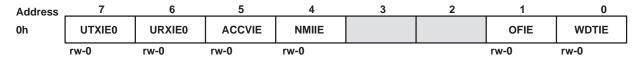
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special function registers

Most interrupt and module-enable bits are collected in the lowest address space. Special-function register bits not allocated to a functional purpose are not physically present in the device. This arrangement provides simple software access.

interrupt enable 1 and 2



WDTIE: Watchdog-timer interrupt enable. Inactive if watchdog mode is selected. Active if watchdog

timer is configured in interval timer mode.

OFIE: Oscillator-fault-interrupt enable
NMIIE: Nonmaskable-interrupt enable

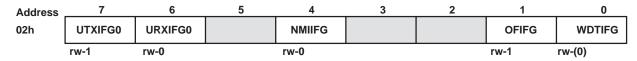
ACCVIE: Flash access violation interrupt enable

URXIE0: USART0: UART and SPI receive-interrupt enable UTXIE0: USART0: UART and SPI transmit-interrupt enable



URXIE1: USART1: UART and SPI receive-interrupt enable UTXIE1: USART1: UART and SPI transmit-interrupt enable

interrupt flag register 1 and 2



WDTIFG: Set on watchdog timer overflow (in watchdog mode) or security key violation. Reset on V_{CC}

power up or a reset condition at the RST/NMI pin in reset mode.

OFIFG: Flag set on oscillator fault

NMIIFG: Set via RST/NMI pin

URXIFG0: USART0: UART and SPI receive flag
UTXIFG0: USART0: UART and SPI transmit flag



URXIFG1: USART1: UART and SPI receive flag
UTXIFG1: USART1: UART and SPI transmit flag

module enable registers 1 and 2

7 6 5 **Address** UTXE0 **URXE0** 04h **USPIE0** rw-0 rw-0

URXE0: USART0: UART receive enable UTXE0: USART0: UART transmit enable

USPIE0: USART0: SPI (synchronous peripheral interface) transmit and receive enable

Address UTXE1 **URXE1** 05h **USPIE1** rw-0

URXE1: USART1: UART receive enable UTXE1: USART1: UART transmit enable

USPIE1: USART1: SPI (synchronous peripheral interface) transmit and receive enable

Legend: rw: Bit Can Be Read and Written

rw-0: Bit Can Be Read and Written. It Is Reset by PUC.

rw-0

SFR Bit Not Present in Device

memory organization

		MSP430F133	MSP430F135	MSP430F147 MSP430F1471	MSP430F148 MSP430F1481	MSP430F149 MSP430F1491
Memory	Size	8KB	16KB	32KB	48KB	60KB
Main: interrupt vector	Flash	0FFFFh – 0FFE0h				
Main: code memory	Flash	0FFFFh – 0E000h	0FFFFh – 0C000h	0FFFFh – 08000h	0FFFFh – 04000h	0FFFFh – 01100h
Information memory	Size	256 Byte				
	Flash	010FFh – 01000h				
Boot memory	Size	1KB	1KB	1KB	1KB	1KB
	ROM	0FFFh – 0C00h				
RAM	Size	256 Byte 02FFh – 0200h	512 Byte 03FFh – 0200h	1KB 05FFh – 0200h	2KB 09FFh – 0200h	2KB 09FFh – 0200h
Peripherals	16-bit	01FFh – 0100h				
	8-bit	0FFh – 010h				
	8-bit SFR	0Fh – 00h				

bootstrap loader (BSL)

The MSP430 bootstrap loader (BSL) enables users to program the flash memory or RAM using a UART serial interface. Access to the MSP430 memory via the BSL is protected by user-defined password. For complete description of the features of the BSL and its implementation, see the Application report Features of the MSP430 Bootstrap Loader, Literature Number SLAA089.

BSL Function	PM, PAG & RTD Package Pins
Data Transmit	13 - P1.1
Data Receive	22 - P2.2



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flash memory

The flash memory can be programmed via the JTAG port, the bootstrap loader, or in-system by the CPU. The CPU can perform single-byte and single-word writes to the flash memory. Features of the flash memory include:

- Flash memory has n segments of main memory and two segments of information memory (A and B) of 128 bytes each. Each segment in main memory is 512 bytes in size.
- Segments 0 to n may be erased in one step, or each segment may be individually erased.
- Segments A and B can be erased individually, or as a group with segments 0-n.
 Segments A and B are also called *information memory*.
- New devices may have some bytes programmed in the information memory (needed for test during manufacturing). The user should perform an erase of the information memory prior to the first use.

		60 KB	48 KB	32 KB	16 KB	8 KB
	Segment 0 w/ Interrupt Vectors	0FFFFh	0FFFFh	0FFFFh	0FFFFh	0FFFFh
	Segment 1	0FE00h 0FDFFh	0FE00h 0FDFFh	0FE00h 0FDFFh	0FE00h 0FDFFh	0FE00h 0FDFFh
	Segment 2	0FC00h 0FBFFh	0FC00h 0FBFFh	0FC00h 0FBFFh	0FC00h 0FBFFh	0FC00h 0FBFFh
Main	•	0FA00h 0F9FFh	0FA00h 0F9FFh	0FA00h 0F9FFh	0FA00h 0F9FFh	0FA00h 0F9FFh
Memory		Š				
		01400h	04400h	08400h	0C400h	0E400h
	Segment n-1	013FFh	043FFh	083FFh	0C3FFh	0E3FFh
		01200h	04200h	08200h	0C200h	0E200h
	Segment n	011FFh	041FFh	081FFh	0C1FFh	0E1FFh
J		01100h	04000h	08000h	0C000h	0E000h
	Segment A	010FFh	010FFh	010FFh	010FFh	010FFh
Information	3.5	01080h	01080h	01080h	01080h	01080h
Memory	Segment B	0107Fh	0107Fh	0107Fh	0107Fh	0107Fh
J	_	01000h	01000h	01000h	01000h	01000h



peripherals

Peripherals are connected to the CPU through data, address, and control busses and can be handled using all instructions. For complete module descriptions, see the *MSP430x1xx Family User's Guide*, literature number SLAU049.

digital I/O

There are six 8-bit I/O ports implemented—ports P1 through P6:

- All individual I/O bits are independently programmable.
- Any combination of input, output, and interrupt conditions is possible.
- Edge-selectable interrupt input capability for all the eight bits of ports P1 and P2.
- Read/write access to port-control registers is supported by all instructions.

oscillator and system clock

The clock system in the MSP430x13x and MSP43x14x(1) family of devices is supported by the basic clock module that includes support for a 32768-Hz watch crystal oscillator, an internal digitally-controlled oscillator (DCO) and a high frequency crystal oscillator. The basic clock module is designed to meet the requirements of both low system cost and low-power consumption. The internal DCO provides a fast turn-on clock source and stabilizes in less than 6 μs. The basic clock module provides the following clock signals:

- Auxiliary clock (ACLK), sourced from a 32768-Hz watch crystal or a high frequency crystal.
- Main clock (MCLK), the system clock used by the CPU.
- Sub-Main clock (SMCLK), the sub-system clock used by the peripheral modules.

watchdog timer

The primary function of the watchdog timer (WDT) module is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the module can be configured as an interval timer and can generate interrupts at selected time intervals.

hardware multiplier (MSP430x14x and MSP430x14x1 Only)

The multiplication operation is supported by a dedicated peripheral module. The module performs 16×16 , 16×8 , 8×16 , and 8×8 bit operations. The module is capable of supporting signed and unsigned multiplication as well as signed and unsigned multiply and accumulate operations. The result of an operation can be accessed immediately after the operands have been loaded into the peripheral registers. No additional clock cycles are required.

USARTO

The MSP430x13x and the MSP430x14x(1) have one hardware universal synchronous/asynchronous receive transmit (USART0) peripheral module that is used for serial data communication. The USART supports synchronous SPI (3 or 4 pin) and asynchronous UART communication protocols, using double-buffered transmit and receive channels.

USART1 (MSP430x14x and MSP430x14x1 Only)

The MSP430x14x(1) has a second hardware universal synchronous/asynchronous receive transmit (USART1) peripheral module that is used for serial data communication. The USART supports synchronous SPI (3 or 4 pin) and asynchronous UART communication protocols, using double-buffered transmit and receive channels. Operation of USART1 is identical to USART0.



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comparator_A

The primary function of the comparator_A module is to support precision slope analog-to-digital conversions, battery-voltage supervision, and monitoring of external analog signals.

ADC12 (Not implemented in the MSP430x14x1)

The ADC12 module supports fast, 12-bit analog-to-digital conversions. The module implements a 12-bit SAR core, sample select control, reference generator and a 16 word conversion-and-control buffer. The conversion-and-control buffer allows up to 16 independent ADC samples to be converted and stored without any CPU intervention.

timer A3

Timer_A3 is a 16-bit timer/counter with three capture/compare registers. Timer_A3 can support multiple capture/compares, PWM outputs, and interval timing. Timer_A3 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

	Timer_A3 Signal Connections								
Input Pin Number	Device Input Signal	Module Input Name	Module Block	Module Output Signal	Output Pin Number				
12 - P1.0	TACLK	TACLK							
	ACLK	ACLK							
	SMCLK	SMCLK	Timer	NA					
21 - P2.1	TAINCLK	INCLK							
13 - P1.1	TA0	CCI0A			13 - P1.1				
22 - P2.2	TA0	CCI0B	0000	TAO	17 - P1.5				
	DV _{SS}	GND	CCR0		27 - P2.7				
	DV _{CC}	Vcc							
14 - P1.2	TA1	CCI1A			14 - P1.2				
	CAOUT (internal)	CCI1B	0004	T	18 - P1.6				
	DVSS	GND	CCR1	TA1	23 - P2.3				
	DV _{CC}	Vcc			ADC12 (internal)				
15 - P1.3	TA2	CCI2A		TA2	15 - P1.3				
	ACLK (internal)	CCI2B	0000		19 - P1.7				
	DVSS	GND	CCR2		24 - P2.4				
	DV _{CC}	Vcc							

timer_B3 (MSP430x13x Only)

Timer_B3 is a 16-bit timer/counter with three capture/compare registers. Timer_B3 can support multiple capture/compares, PWM outputs, and interval timing. Timer_B3 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.



timer_B7 (MSP430x14x and MSP430x14x1 Only)

Timer_B7 is a 16-bit timer/counter with seven capture/compare registers. Timer_B7 can support multiple capture/compares, PWM outputs, and interval timing. Timer_B7 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

	_	Timer_B3/B7 Si	ignal Connections	<u>;</u> †	
Input Pin Number	Device Input Signal	Module Input Name	Module Block	Module Output Signal	Output Pin Number
43 - P4.7	TBCLK	TBCLK			
	ACLK	ACLK			
	SMCLK	SMCLK	Timer	NA	
43 - P4.7	TBCLK	INCLK			
36 - P4.0	TB0	CCI0A			36 - P4.0
36 - P4.0	TB0	CCI0B		ТВО	ADC12 (internal)
	DVSS	GND	CCR0		
	DVCC	VCC			
37 - P4.1	TB1	CCI1A			37 - P4.1
37 - P4.1	TB1	CCI1B			ADC12 (internal)
	DVSS	GND	CCR1	TB1	
	DVCC	VCC			
38 - P4.2	TB2	CCI2A		TB2	38 - P4.2
38 - P4.2	TB2	CCI2B			
	DVSS	GND	CCR2		
	DVCC	Vcc			
39 - P4.3	TB3	CCI3A			39 - P4.3
39 - P4.3	TB3	CCI3B			
	DV _{SS}	GND	CCR3	TB3	
	DVCC	Vcc			
40 - P4.4	TB4	CCI4A			40 - P4.4
40 - P4.4	TB4	CCI4B			
	DVSS	GND	CCR4	TB4	
	DVCC	VCC			
41 - P4.5	TB5	CCI5A			41 - P4.5
41 - P4.5	TB5	CCI5B			
	DVSS	GND	CCR5	TB5	
	DVCC	Vcc			
42 - P4.6	TB6	CCI6A			42 - P4.6
	ACLK (internal)	CCI6B	007-		
	DVSS	GND	CCR6	TB6	
	DVCC	VCC			

[†] Timer_B3 implements three capture/compare blocks (CCR0, CCR1 and CCR2 only).

peripheral file map

	PERIPHERALS WITH WORD ACCE	SS						
Watchdog Watchdog Timer control WDTCTL 0120h								
Timer_B7/	Timer_B interrupt vector	TBIV	011Eh					
Timer_B3 (see Note 1)	Timer_B control	TBCTL	0180h					
(See Note 1)	Capture/compare control 0	TBCCTL0	0182h					
	Capture/compare control 1 TBCCTL1 Capture/compare control 2 TBCCTL2							
	Capture/compare control 3 TBCCTL3 C							
	Capture/compare control 4 TBCCTL4							
	Capture/compare control 4 TBCCT Capture/compare control 5 TBCCT		018Ch					
	Capture/compare control 6	TBCCTL6	018Eh					
	Timer_B register	TBR	0190h					
	Capture/compare register 0	TBCCR0	0192h					
	Capture/compare register 1	TBCCR1	0194h					
	Capture/compare register 2	TBCCR2	0196h					
	Capture/compare register 3	TBCCR3	0198h					
	Capture/compare register 4	TBCCR4	019Ah					
	Capture/compare register 5	TBCCR5	019Ch					
	Capture/compare register 6	TBCCR6	019Eh					
Timer_A3	Timer_A interrupt vector	TAIV	012Eh					
	Timer_A control	TACTL	0160h					
	Capture/compare control 0	TACCTL0	0162h					
	Capture/compare control 1	TACCTL1	0164h					
	Capture/compare control 2	TACCTL2	0166h					
	Reserved		0168h					
	Reserved		016Ah					
	Reserved		016Ch					
	Reserved		016Eh					
	Timer_A register	TAR	0170h					
	Capture/compare register 0	TACCR0	0172h					
	Capture/compare register 1	TACCR1	0174h					
	Capture/compare register 2	TACCR2	0176h					
	Reserved		0178h					
	Reserved		017Ah					
	Reserved		017Ch					
	Reserved		017Eh					
Hardware	Sum extend	SUMEXT	013Eh					
Multiplier	Result high word	RESHI	013Ch					
(MSP430x14x and MSP430x14x1	Result low word	RESLO	013Ah					
only)	Second operand	OP2	0138h					
**	Multiply signed +accumulate/operand1	MACS	0136h					
	Multiply+accumulate/operand1	MAC	0134h					
	Multiply signed/operand1	MPYS	0132h					
	Multiply unsigned/operand1	MPY	0132h					
	in MSP430x14x(1) family has 7 CCRs. Timer I							

NOTE 1: Timer_B7 in MSP430x14x(1) family has 7 CCRs, Timer_B3 in MSP430x13x family has 3 CCRs.



peripheral file map (continued)

	PERIPHERALS WITH WORD ACCESS (CONTIN	NUED)	
Flash	Flash control 3	FCTL3	012Ch
	Flash control 2	FCTL2	012Ah
	Flash control 1	FCTL1	0128h
ADC12	Conversion memory 15	ADC12MEM15	015Eh
(Not implemented in the MSP430x14x1)	Conversion memory 14	ADC12MEM14	015Ch
the WSF430x14x1)	Conversion memory 13	ADC12MEM13	015Ah
	Conversion memory 12	ADC12MEM12	0158h
	Conversion memory 11	ADC12MEM11	0156h
	Conversion memory 10	ADC12MEM10	0154h
	Conversion memory 9	ADC12MEM9	0152h
	Conversion memory 8	ADC12MEM8	0150h
	Conversion memory 7	ADC12MEM7	014Eh
	Conversion memory 6	ADC12MEM6	014Ch
	Conversion memory 5	ADC12MEM5	014Ah
	Conversion memory 4	ADC12MEM4	0148h
	Conversion memory 3	ADC12MEM3	0146h
	Conversion memory 2	ADC12MEM2	0144h
	Conversion memory 1	ADC12MEM1	0142h
	Conversion memory 0	ADC12MEM0	0140h
	Interrupt-vector-word register	ADC12IV	01A8h
	Inerrupt-enable register	ADC12IE	01A6h
	Inerrupt-flag register	ADC12IFG	01A4h
	Control register 1	ADC12CTL1	01A2h
	Control register 0	ADC12CTL0	01A0h
	ADC memory-control register15	ADC12MCTL15	08Fh
	ADC memory-control register14	ADC12MCTL14	08Eh
	ADC memory-control register13	ADC12MCTL13	08Dh
	ADC memory-control register12	ADC12MCTL12	08Ch
	ADC memory-control register11	ADC12MCTL11	08Bh
	ADC memory-control register10	ADC12MCTL10	08Ah
	ADC memory-control register9	ADC12MCTL9	089h
	ADC memory-control register8	ADC12MCTL8	088h
	ADC memory-control register7	ADC12MCTL7	087h
	ADC memory-control register6	ADC12MCTL6	086h
	ADC memory-control register5 ADC memory-control register4	ADC12MCTL5 ADC12MCTL4	085h 084h
	ADC memory-control register4 ADC memory-control register3	ADC12MCTL4 ADC12MCTL3	084h 083h
	ADC memory-control registers ADC memory-control register2	ADC12MCTL3	082h
	ADC memory-control register1	ADC12MCTL1	081h
	ADC memory-control register0	ADC12MCTL0	080h



peripheral file map (continued)

PERIPHERALS WITH BYTE ACCESS							
USART1	Transmit buffer	U1TXBUF	07Fh				
(MSP430x14x and	Receive buffer	U1RXBUF	07Eh				
MSP430x14x1 only)	Baud rate	U1BR1	07Dh				
	Baud rate	U1BR0	07Ch				
	Modulation control	U1MCTL	07Bh				
	Receive control	U1RCTL	07Ah				
	Transmit control	U1TCTL	079h				
	USART control	U1CTL	078h				
USART0	Transmit buffer	U0TXBUF	077h				
	Receive buffer	U0RXBUF	076h				
	Baud rate	U0BR1	075h				
	Baud rate	U0BR0	074h				
	Modulation control	U0MCTL	073h				
	Receive control	U0RCTL	072h				
	Transmit control	U0TCTL	071h				
	USART control	U0CTL	070h				
Comparator_A	Comparator_A port disable	CAPD	05Bh				
	Comparator_A control2	CACTL2	05Ah				
	Comparator_A control1	CACTL1	059h				
Basic Clock	Basic clock system control2	BCSCTL2	058h				
	Basic clock system control1	BCSCTL1	057h				
	DCO clock frequency control	DCOCTL	056h				
Port P6	Port P6 selection	P6SEL	037h				
	Port P6 direction	P6DIR	036h				
	Port P6 output	P6OUT	035h				
	Port P6 input	P6IN	034h				
Port P5	Port P5 selection	P5SEL	033h				
	Port P5 direction	P5DIR	032h				
	Port P5 output	P5OUT	031h				
	Port P5 input	P5IN	030h				
Port P4	Port P4 selection	P4SEL	01Fh				
	Port P4 direction	P4DIR	01Eh				
	Port P4 output	P4OUT	01Dh				
	Port P4 input	P4IN	01Ch				
Port P3	Port P3 selection	P3SEL	01Bh				
	Port P3 direction	P3DIR	01Ah				
	Port P3 output	P3OUT	019h				
	Port P3 input	P3IN	018h				
Port P2	Port P2 selection	P2SEL	02Eh				
	Port P2 interrupt enable	P2IE	02Dh				
	Port P2 interrupt-edge select	P2IES	02Ch				
	Port P2 interrupt flag	P2IFG	02Bh				
	Port P2 direction	P2DIR	02Ah				
	Port P2 output	P2OUT	029h				
	Port P2 input	P2IN	028h				



peripheral file map (continued)

	PERIPHERALS WITH BYTE ACCESS (CONTINUED)						
Port P1	Port P1 selection	P1SEL	026h				
	Port P1 interrupt enable	P1IE	025h				
	Port P1 interrupt-edge select	P1IES	024h				
	Port P1 interrupt flag	P1IFG	023h				
Port P1 direction P1DIR							
	Port P1 output	P1OUT	021h				
	Port P1 input	P1IN	020h				
Special Functions	SFR module enable 2	ME2	005h				
	SFR module enable 1	ME1	004h				
	SFR interrupt flag2	IFG2	003h				
	SFR interrupt flag1	IFG1	002h				
	SFR interrupt enable2	IE2	001h				
	SFR interrupt enable1	IE1	000h				

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Voltage applied at V _{CC} to V _{SS}	0.3 V to + 4.1 V
Voltage applied to any pin (see Note)	0.3 V to V _{CC} +0.3 V
Diode current at any device terminal	±2 mA
Storage temperature (unprogrammed device)	–55°C to 150°C
Storage temperature (programmed device)	40°C to 85°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE: All voltages referenced to V_{SS}. The JTAG fuse-blow voltage, V_{FB}, is allowed to exceed the absolute maximum rating. The voltage is applied to the TDI/TCLK pin when blowing the JTAG fuse.

recommended operating conditions

PARAMI	ETER		MIN	NOM	MAX	UNITS
Supply voltage during program execution, V _{CC} (A	VCC = DVCC = VCC)	MSP430F13x, MSP430F14x(1)	1.8		3.6	V
Supply voltage during flash memory programming $(AV_{CC} = DV_{CC} = V_{CC})$	MSP430F13x, MSP430F14x(1)	2.7		3.6	V	
Supply voltage, VSS (AVSS = DVSS = VSS)			0.0		0.0	V
Operating free-air temperature range, TA		MSP430x13x MSP430x14x(1)	-40		85	°C
	LF selected, XTS=0	Watch crystal		32768		Hz
LFXT1 crystal frequency, f _(LFXT1) (see Notes 1 and 2)	XT1 selected, XTS=1	Ceramic resonator	450		8000	kHz
(See Notes 1 and 2)	XT1 selected, XTS=1	Crystal	1000		8000	kHz
VTO 116 6		Ceramic resonator	450		8000	
XT2 crystal frequency, f(XT2)		Crystal	1000		8000	kHz
		V _{CC} = 1.8 V	DC		4.15	
Processor frequency (signal MCLK), f(System)		V _{CC} = 3.6 V	DC		8	MHz

- NOTES: 1. In LF mode, the LFXT1 oscillator requires a watch crystal. A 5.1MΩ resistor from XOUT to V_{SS} is recommended when V_{CC} < 2.5 V. In XT1 mode, the LFXT1 and XT2 oscillators accept a ceramic resonator or crystal up to 4.15MHz at V_{CC} ≥ 2.2 V. In XT1 mode, the LFXT1 and XT2 oscillators accept a ceramic resonator or crystal up to 8MHz at V_{CC} ≥ 2.8 V.
 - 2. In LF mode, the LFXT1 oscillator requires a watch crystal. In XT1 mode, LFXT1 accepts a ceramic resonator or a crystal.

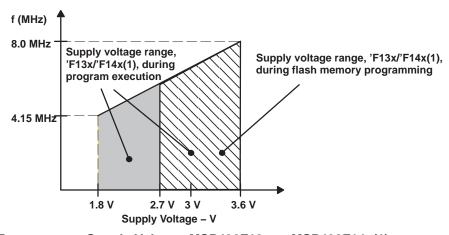


Figure 1. Frequency vs Supply Voltage, MSP430F13x or MSP430F14x(1)

electrical characteristics over recommended operating free-air temperature (unless otherwise noted)

supply current into AV_{CC} + DV_{CC} excluding external current

	PARAMETER	TEST COND	ITIONS	MIN	NOM	MAX	UNIT
Active mode, (see Note 1) f(MCLK) = f(SMCLK) = 1 MHz,		$T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	V _{CC} = 2.2 V		280	350	^
I(AM)	f(ACLK) = 32,768 Hz XTS=0, SELM=(0,1)	1A = -40°C to 85°C	V _{CC} = 3 V		420	560	μΑ
Lean	Active mode, (see Note 1) $f(MCLK) = f(SMCLK) = 4 096 Hz,$	T 40°C to 95°C	V _{CC} = 2.2 V		2.5	7	^
I(AM)	f(ACLK) = 4,096 Hz XTS=0, SELM=(0,1) XTS=0, SELM=3	$T_A = -40$ °C to 85°C	V _{CC} = 3 V		9	20	μΑ
la puo	Low-power mode, (LPM0)	$T_{\Delta} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C}$	V _{CC} = 2.2 V		32	45	μA
I(LPM0)	(see Note 1)	1A = -40 C to 65 C	VCC = 3 V		55	70	μΑ
	Low-power mode, (LPM2), f(MCLK) = f (SMCLK) = 0 MHz,	$T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	V _{CC} = 2.2 V		11	14	^
I _(LPM2)	f(ACLK) = 32.768 Hz, SCG0 = 0		VCC = 3 V		17	22	μΑ
		T _A = −40°C	V _{CC} = 2.2 V		0.8	1.5	μΑ
		T _A = 25°C			0.9	1.5	
10	Low-power mode, (LPM3)	T _A = 85°C			1.6	2.8	
I(LPM3)	f(MCLK) = f(SMCLK) = 0 MHz, f(ACLK) = 32,768 Hz, SCG0 = 1 (see Note 2)	T _A = -40°C			1.8	2.2	μΑ
	(1.0_1.1)	$T_A = 25^{\circ}C$	VCC = 3 V		1.6	1.9	
		T _A = 85°C			2.3	3.9	
		T _A = -40°C			0.1	0.5	
		T _A = 25°C	V _{CC} = 2.2 V		0.1	0.5	μΑ
la pue	Low-power mode, (LPM4)	T _A = 85°C			8.0	2.5	
I(LPM4)	f(MCLK) = 0 MHz, f(SMCLK) = 0 MHz, f(ACLK) = 0 Hz, SCG0 = 1	T _A = -40°C			0.1	0.5	μΑ
	v · · · /	T _A = 25°C	V _{CC} = 3 V		0.1	0.5	
		T _A = 85°C			0.8	2.5	

NOTES: 1. Timer_B is clocked by f(DCOCLK) = 1 MHz. All inputs are tied to 0 V or to VCC. Outputs do not source or sink any current.

Current consumption of active mode versus system frequency, F-version

$$I(AM) = I(AM) [1 MHz] \times f(System) [MHz]$$

Current consumption of active mode versus supply voltage, F-version

$$I_{(AM)} = I_{(AM)[3\ V]} + 175\ \mu A/V \times (V_{CC} - 3\ V)$$

^{2.} Timer_B is clocked by f(ACLK) = 32,768 Hz. All inputs are tied to 0 V or to V_{CC}. Outputs do not source or sink any current. The current consumption in LPM2 and LPM3 are measured with ACLK selected.

MSP430x13x, MSP430x14x, MSP430x14x1 MIXED SIGNAL MICROCONTROLLER

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electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

SCHMITT-trigger inputs – Ports P1, P2, P3, P4, P5, and P6

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
.,	Death and a facilities of the selection of	V _{CC} = 2.2 V	1.1	1.5	.,
V _{IT+}	Positive-going input threshold voltage	V _{CC} = 3 V	1.5	1.9	V
V	Nametica mains is not through all colleges	V _{CC} = 2.2 V	0.4	0.9	
V_{IT-}	Negative-going input threshold voltage	V _{CC} = 3 V	0.90	1.3	V
٧/.	Input voltage hyptoresis (// //)	V _{CC} = 2.2 V	0.3	1.1	V
V _{hys} Ir	Input voltage hysteresis (V _{IT+} – V _{IT-})	V _{CC} = 3 V	0.5	1]

standard inputs - RST/NMI; JTAG: TCK, TMS, TDI/TCLK, TDO/TDI

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
V _{IL}	Low-level input voltage	V _C C = 2.2 V / 3 V	VSS	V _{SS} +0.	6 V
٧ıн	High-level input voltage	vCC = 2.2 v / 3 v	0.8×VCC	VC) V

inputs Px.x, TAx, TBx

	PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	UNIT
			2.2 V/3 V	1.5			cycle
t(int)	External interrupt timing	Port P1, P2: P1.x to P2.x, external trigger signal for the interrupt flag, (see Note 1)	2.2 V	62			
	To the monaphing, (eee Note 1)	3 V	50			ns	
_ ,		TA0, TA1, TA2	2.2 V	62			
^t (cap)	t(cap) Timer_A, Timer_B capture timing	TB0, TB1, TB2, TB3, TB4, TB5, TB6 (see Note 2)	3 V	50			ns
f(TAext)	Timer_A, Timer_B clock		2.2 V			8	MI I-
f(TBext)	frequency externally applied to pin	TACLK, TBCLK, INCLK: $t_{(H)} = t_{(L)}$	3 V			10	MHz
f(TAint)	Timer_A, Timer_B clock	SMCI K or ACI K signal calcuted	2.2 V			8	NAL I-
f(TBint)	frequency	SMCLK or ACLK signal selected	3 V			10	MHz

NOTES: 1. The external signal sets the interrupt flag every time the minimum t_(int) cycle and time parameters are met. It may be set even with trigger signals shorter than t_(int). Both the cycle and timing specifications must be met to ensure the flag is set. t_(int) is measured in MCLK cycles

2. Seven capture/compare registers in 'x14x(1) and three capture/compare registers in 'x13x.

leakage current (see Note 1)

PARAMETER			TEST CONDITIONS			TYP	MAX	UNIT
I _{lkg} (P1.x)	Leakane	Port P1	V _(P1.x) (see Note 2)				±50	
I _{lkg(P2.x)}	Leakage current (see	Port P2	V _(P2.3) V _(P2.4) (see Note 2)	V _{CC} = 2.2 V/3 V			±50	nA
I _{lkg(P6.x)}	Note 1)	Port P6	V _(P6.x) (see Note 2)				±50	

NOTES: 1. The leakage current is measured with VSS or VCC applied to the corresponding pin(s), unless otherwise noted.

2. The port pin must be selected as input and there must be no optional pullup or pulldown resistor.



electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

outputs - Ports P1, P2, P3, P4, P5, and P6

	PARAMETER	TEST	CONDITIONS		MIN	TYP MAX	UNIT
		$I_{OH(max)} = -1 \text{ mA},$	$V_{CC} = 2.2 \text{ V},$	See Note 1	V _{CC} -0.25	VCC	
VOH	High-level output voltage	$I_{OH(max)} = -6 \text{ mA},$	$V_{CC} = 2.2 \text{ V},$	See Note 2	VCC-0.6	VCC	V
		$I_{OH(max)} = -1 \text{ mA},$	$V_{CC} = 3 V$,	See Note 1	V _{CC} -0.25	Vcc	V
		$I_{OH(max)} = -6 \text{ mA},$	$V_{CC} = 3 V$,	See Note 2	VCC-0.6	Vcc	
		$I_{OL(max)} = 1.5 \text{ mA},$	$V_{CC} = 2.2 \text{ V},$	See Note 1	V _{SS}	V _{SS} +0.25	
V.0.	Low-level output voltage	$I_{OL(max)} = 6 \text{ mA},$	$V_{CC} = 2.2 \text{ V},$	See Note 2	V _{SS}	V _{SS} +0.6	V
VOL		$I_{OL(max)} = 1.5 \text{ mA},$	$V_{CC} = 3 V$,	See Note 1	VSS	V _{SS} +0.25	٧
		$I_{OL(max)} = 6 \text{ mA},$	V _C C = 3 V,	See Note 2	VSS	V _{SS} +0.6	

- NOTES: 1. The maximum total current, I_{OH(max)} and I_{OL(max)}, for all outputs combined, should not exceed ±6 mA to satisfy the maximum specified voltage drop.
 - 2. The maximum total current, I_{OH(max)} and I_{OL(max)}, for all outputs combined, should not exceed ±24 mA to satisfy the maximum specified voltage drop.

output frequency

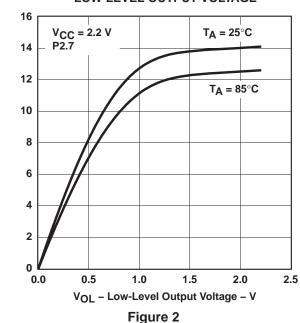
	PARAMETER	TEST	CONDITIONS	MIN	TYP	MAX	UNIT
f _{TAx}	TA02, TB0-TB6, Internal clock source, SMCLK signal applied (see Note 1)	C _L = 20 pF	C _L = 20 pF			fSystem	M1 I-
fACLK, fMCLK, fSMCLK	P5.6/ACLK, P5.4/MCLK, P5.5/SMCLK	C _L = 20 pF			fSystem	MHz	
		P2.0/ACLK	fACLK = fLFXT1 = fXT1	40%		60%	
		$C_L = 20 \text{ pF},$ $V_{CC} = 2.2 \text{ V} / 3 \text{ V}$	fACLK = fLFXT1 = fLF	30%		70%	
			fACLK = fLFXT1/n		50%		
			fSMCLK = fLFXT1 = fXT1	40%		60%	
^t Xdc	Duty cycle of output frequency,	D4 4/014011/	fSMCLK = fLFXT1 = fLF	35%		65%	
		P1.4/SMCLK, C _L = 20 pF, V _{CC} = 2.2 V / 3 V	fSMCLK = fLFXT1/n	50%– 15 ns	50%	50%– 15 ns	
		-60 == 1701	fSMCLK = fDCOCLK	50%– 15 ns	50%	50%– 15 ns	

NOTE 1: The limits of the system clock MCLK has to be met; the system (MCLK) frequency should not exceed the limits. MCLK and SMCLK frequencies can be different.

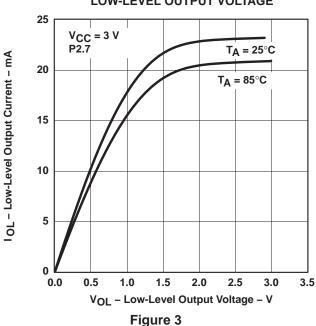
electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

outputs - Ports P1, P2, P3, P4, P5, and P6 (continued)

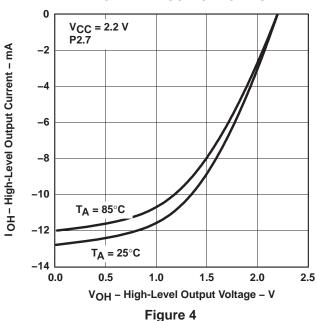
TYPICAL LOW-LEVEL OUTPUT CURRENT vs LOW-LEVEL OUTPUT VOLTAGE



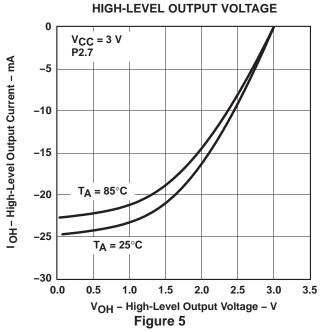
TYPICAL LOW-LEVEL OUTPUT CURRENT vs LOW-LEVEL OUTPUT VOLTAGE



TYPICAL HIGH-LEVEL OUTPUT CURRENT vs HIGH-LEVEL OUTPUT VOLTAGE



TYPICAL HIGH-LEVEL OUTPUT CURRENT vs





I OL - Low-Level Output Current - mA

electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

wake-up LPM3

PARAMETER	TEST	TEST CONDITIONS			MAX	UNIT	
	f = 1 MHz				6		
t _(LPM3) Delay time	f = 2 MHz	V _{CC} = 2.2 V/3 V			6	μs	
	f = 3 MHz	1			6		

RAM

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VRAMh	CPU HALTED (see Note 1)	1.6	•		V

NOTE 1: This parameter defines the minimum supply voltage when the data in program memory RAM remain unchanged. No program execution should take place during this supply voltage condition.

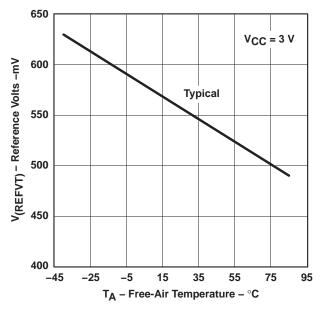
Comparator_A (see Note 1)

	PARAMETER	TEST CONDITION	IS	MIN	TYP	MAX	UNIT
Lan		CAON 4 CARSEL A CAREE A	V _{CC} = 2.2 V		25	40	^
I(DD)		CAON=1, CARSEL=0, CAREF=0	VCC = 3 V		45	60	μΑ
		CAON=1, CARSEL=0,	V _{CC} = 2.2 V		30	50	
^I (Refladder/F	Refdiode)	CAREF=1/2/3, no load at P2.3/CA0/TA1 and P2.4/CA1/TA2	V _{CC} = 3 V		45	71	μΑ
V _(IC)	Common-mode input voltage	CAON =1	V _{CC} = 2.2 V/3 V	0		V _{CC} -1	V
V(Ref025)	Voltage @ 0.25 V _{CC} node	PCA0=1, CARSEL=1, CAREF=1, no load at P2.3/CA0/TA1 and P2.4/CA1/TA2	V _{CC} = 2.2 V/3 V	0.23	0.24	0.25	
V(Ref050)	Voltage @ 0.5V _{CC} node	PCA0=1, CARSEL=1, CAREF=2, no load at P2.3/CA0/TA1 and P2.4/CA1/TA2	V _{CC} = 2.2 V/3 V	0.47	0.48	0.5	
		PCA0=1, CARSEL=1, CAREF=3,	V _{CC} = 2.2 V	390	480	540	
V(RefVT)	(see Figure 6)	no load at P2.3/CA0/TA1 and P2.4/CA1/TA2 T _A = 85°C	V _{CC} = 3 V	400	490	550	mV
V _(offset)	Offset voltage	See Note 2	V _{CC} = 2.2 V/3 V	-30		30	mV
V _{hys}	Input hysteresis	CAON=1	V _{CC} = 2.2 V/3 V	0	0.7	1.4	mV
		T _A = 25°C, Overdrive 10 mV,	V _{CC} = 2.2 V	130	210	300	
		Without filter: CAF=0	VCC = 3 V	80	150	240	ns
^t (response L	H)	T _A = 25°C, Overdrive 10 mV,	V _{CC} = 2.2 V	1.4	1.9	3.4	
		With filter: CAF=1	VCC = 3 V	0.9	1.5	2.6	μs
		T _A = 25°C, Overdrive 10 mV,	V _{CC} = 2.2 V	130	210	300	
		Without filter: CAF=0	V _{CC} = 3 V	80	150	240	ns
t(response F	IL)	T _A = 25°C, Overdrive 10 mV,	V _{CC} = 2.2 V	1.4	1.9	3.4	
		With filter: CAF=1	V _{CC} = 3 V	0.9	1.5	2.6	μs

NOTES: 1. The leakage current for the Comparator_A terminals is identical to I_{lkg(Px.x)} specification.



The input offset voltage can be cancelled by using the CAEX bit to invert the Comparator_A inputs on successive measurements. The two successive measurements are then summed together.



650 V_{CC} = 2.2 V 600 V(REFVT) - Reference Volts -mV **Typical** 550 500 450 400 -45 -25 15 35 55 75 95 T_A – Free-Air Temperature – $^{\circ}C$

Figure 6. $V_{(RefVT)}$ vs Temperature, $V_{CC} = 3 V$

Figure 7. $V_{(RefVT)}$ vs Temperature, V_{CC} = 2.2 V

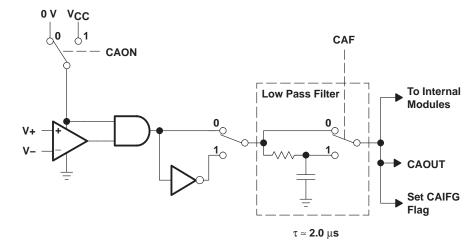


Figure 8. Block Diagram of Comparator_A Module

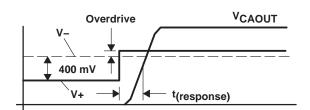


Figure 9. Overdrive Definition



PUC/POR

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
t(POR_Delay)	Internal time delay to release POR				150	250	μs
	V _{CC} threshold at which POR	$T_A = -40^{\circ}C$]	1.4		1.8	V
V _{POR}	release delay time begins (see Note 1)	$T_A = 25^{\circ}C$	V _{CC} = 2.2 V/3 V	1.1		1.5	V
		T _A = 85°C		0.8		1.2	V
V _(min)	V _{CC} threshold required to generate a POR (see Note 2)	V _{CC} dV/dt ≥ 1V/ms		0.2			V
t(reset)	RST/NMI low time for PUC/POR	Reset is accepted internally		2			μs

NOTES: 1. V_{CC} rise time $dV/dt \ge 1V/ms$.

2. When driving V_{CC} low in order to generate a POR condition, V_{CC} should be driven to 200mV or lower with a dV/dt equal to or less than -1V/ms. The corresponding rising V_{CC} must also meet the dV/dt requirement equal to or greater than +1V/ms.

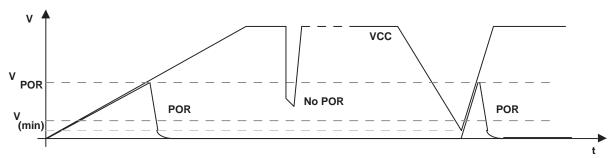


Figure 10. Power-On Reset (POR) vs Supply Voltage

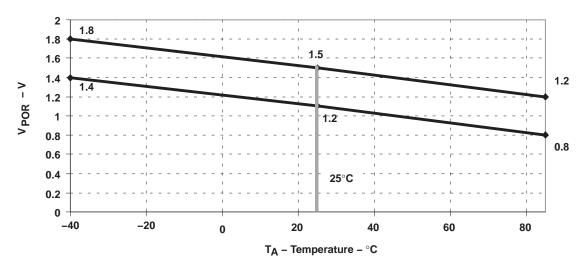


Figure 11. V_{POR} vs Temperature

DCO (see Note 1)

PARAMETER	TEST CONDITIONS		MIN	NOM	MAX	UNIT
_	R _{Sel} = 0, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	0.08	0.12	0.15	
f(DCO03)		VCC = 3 V	0.08	0.13	0.16	MHz
	R _{Sel} = 1, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	0.14	0.19	0.23	
f(DCO13)		VCC = 3 V	0.14	0.18	0.22	MHz
.	$R_{Sel} = 2$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25$ °C	V _{CC} = 2.2 V	0.22	0.30	0.36	N 41 1-
f(DCO23)		V _{CC} = 3 V	0.22	0.28	0.34	MHz
.	$R_{Sel} = 3$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25$ °C	$V_{CC} = 2.2 \text{ V}$	0.37	0.49	0.59	N 41 1-
f(DCO33)		V _{CC} = 3 V	0.37	0.47	0.56	MHz
	R _{Sel} = 4, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	0.61	0.77	0.93	
f(DCO43)		V _{CC} = 3 V	0.61	0.75	0.90	MHz
4	R _{Sel} = 5, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	1	1.2	1.5	MHz
f(DCO53)		V _{CC} = 3 V	1	1.3	1.5	IVIHZ
f(DOOD)	$R_{Sel} = 6$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25$ °C	$V_{CC} = 2.2 \text{ V}$	1.6	1.9	2.2	MHz
f(DCO63)		V _{CC} = 3 V	1.69	2.0	2.29	IVII IZ
4	$R_{Sel} = 7$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25$ °C	$V_{CC} = 2.2 \text{ V}$	2.4	2.9	3.4	N 41 1-
f(DCO73)		V _{CC} = 3 V	2.7	3.2	3.65	MHz
f(DCO47)	R _{sel} = 4, DCO = 7, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V/3 V	fDCO40 ×1.7	fDCO40 × 2.1	fDCO40 × 2.5	MHz
	D 7 DOO 7 MOD 0 DOOD 0 T 0500	V _{CC} = 2.2 V	4	4.5	4.9	
f(DCO77)	R _{Sel} = 7, DCO = 7, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 3 V	4.4	4.9	5.4	MHz
S _(Rsel)	S _R = f _{Rsel+1} / f _{Rsel}	V _{CC} = 2.2 V/3 V	1.35	1.65	2	
S _(DCO)	S _{DCO} = f _{DCO+1} / f _{DCO}	V _{CC} = 2.2 V/3 V	1.07	1.12	1.16	
	Temperature drift, R _{sel} = 4, DCO = 3, MOD = 0	V _{CC} = 2.2 V	-0.31	-0.36	-0.40	0/ /00
Dt	(see Note 2)	V _{CC} = 3 V	-0.33	-0.38	-0.43	%/°C
DV	Drift with V _{CC} variation, R _{Sel} = 4, DCO = 3, MOD = 0 (see Note 2)	V _{CC} = 2.2 V/3 V	0	5	10	%/V

NOTES: 1. The DCO frequency may not exceed the maximum system frequency defined by parameter processor frequency, f(System).



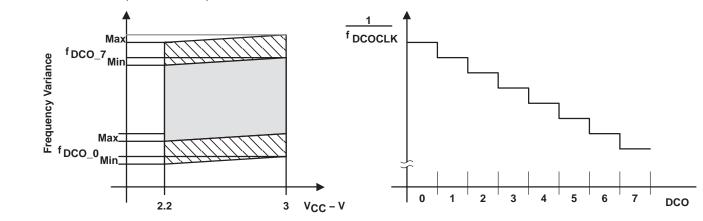


Figure 12. DCO Characteristics

electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

main DCO characteristics

- Individual devices have a minimum and maximum operation frequency. The specified parameters for fDCOx0 to fDCOx7 are valid for all devices.
- All ranges selected by Rsel(n) overlap with Rsel(n+1): Rsel0 overlaps with Rsel1, ... Rsel6 overlaps with Rsel7.
- DCO control bits DCO0, DCO1, and DCO2 have a step size as defined by parameter SDCO.
- Modulation control bits MOD0 to MOD4 select how often fDCO+1 is used within the period of 32 DCOCLK cycles. The frequency f(DCO) is used for the remaining cycles. The frequency is an average equal to f(DCO) × (2^{MOD/32}).

DCO when using R_{OSC} (see Note 1)

PARAMETER	TEST CONDITIONS	Vcc	MIN NOM	MAX	UNIT
f _{DCO} , DCO output frequency	R _{sel} = 4, DCO = 3, MOD = 0, DCOR = 1,	2.2 V	1.8±15%		MHz
IDCO, DCO output frequency	$T_A = 25^{\circ}C$	3 V	1.95±15%		MHz
D _t , Temperature drift	R _{Sel} = 4, DCO = 3, MOD = 0, DCOR = 1	2.2 V/3 V	±0.1		%/°C
D _V , Drift with V _{CC} variation	R _{Sel} = 4, DCO = 3, MOD = 0, DCOR = 1	2.2 V/3 V	10		%/V

NOTES: 1. $R_{OSC} = 100 k\Omega$. Metal film resistor, type 0257. 0.6 watt with 1% tolerance and $T_K = \pm 50 ppm/^{\circ}C$.

crystal oscillator, LFXT1 oscillator (see Note 1)

	PARAMETER	TEST CONDITIONS	MIN	NOM	MAX	UNIT
Commo	Integrated input conscitous	XTS=0; LF oscillator selected V _{CC} = 2.2 V/3 V	12			~F
C _{XIN}	Integrated input capacitance	XTS=1; XT1 oscillator selected V _{CC} = 2.2 V/3 V	2		pF	
	Integrated output capacitance	XTS=0; LF oscillator selected V _{CC} = 2.2 V/3 V	12			
CXOUT		XTS=1; XT1 oscillator selected V _{CC} = 2.2 V/3 V	2		pF	
V _{IL}	Input levels at XIN	Va a 22 V/2 V (ago Noto 2)	VSS	(0.2 × V _{CC}	V
V _{IH}	Input levels at ATM	V _{CC} = 2.2 V/3 V (see Note 2)	$0.8 \times V_{CC}$		VCC	V

- NOTES: 1. The oscillator needs capacitors at both terminals, with values specified by the crystal manufacturer.
 - 2. Applies only when using an external logic-level clock source. Not applicable when using a crystal or resonator.

crystal oscillator, XT2 oscillator (see Note 1)

	PARAMETER	TEST CONDITIONS	MIN	NOM	MAX	UNIT
C _{XT2IN}	Input capacitance	V _{CC} = 2.2 V/3 V	2			pF
C _{XT2OUT}	Output capacitance	V _{CC} = 2.2 V/3 V	2			pF
VIL	Innut lavale at VTOIN	V 0.0 V/0 V (occ Note 0)	VSS	0.	2×V _{CC}	V
VIH	Input levels at XT2IN	V _{CC} = 2.2 V/3 V (see Note 2)	0.8 × V _{CC}		VCC	V

- NOTES: 1. The oscillator needs capacitors at both terminals, with values specified by the crystal manufacturer.
 - 2. Applies only when using an external logic-level clock source. Not applicable when using a crystal or resonator.

USARTO, USART1 (see Note 1)

	PARAMETER	TEST CONDITIONS	MIN	NOM	MAX	UNIT
4	LICADTO/4: deglitch time	V _{CC} = 2.2 V	200	430	800	20
t _(\tau)	USART0/1: deglitch time	V _{CC} = 3 V	150	280	500	ns

NOTE 1: The signal applied to the USART0/1 receive signal/terminal (URXD0/1) should meet the timing requirements of $t_{(\tau)}$ to ensure that the URXS flip-flop is set. The URXS flip-flop is set with negative pulses meeting the minimum-timing condition of $t_{(\tau)}$. The operating conditions to set the flag must be met independently from this timing constraint. The deglitch circuitry is active only on negative transitions on the URXD0/1 line.



electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

12-bit ADC, power supply and input range conditions (see Note 1)

	PARAMETER	TEST CONDITIONS	3	MIN	NOM	MAX	UNIT
AVCC	Analog supply voltage	AV _{CC} and DV _{CC} are connected toge AV _{SS} and DV _{SS} are connected toge V(AVSS) = V(DVSS) = 0 V		2.2		3.6	٧
V(P6.x/Ax)	Analog input voltage range (see Note 2)	All P6.0/A0 to P6.7/A7 terminals. And selected in ADC12MCTLx register an $0 \le x \le 7$; $V_{(AVSS)} \le V_{P6.x/Ax} \le V_{(AVSS)}$	0		VAVCC	٧	
	Operating supply current	fADC12CLK = 5.0 MHz	2.2 V		0.65	1.3	
I _{ADC12}	into AV _{CC} terminal (see Note 3)	ADC12ON = 1, REFON = 0 SHT0=0, SHT1=0, ADC12DIV=0	3 V		0.8	1.6	mA
	Operating supply current	fADC12CLK = 5.0 MHz ADC12ON = 0, REFON = 1, REF2_5V = 1	3 V		0.5	0.8	mA
IREF+	into AV _{CC} terminal (see Note 4)	fADC12CLK = 5.0 MHz	2.2 V		0.5	0.8	
		ADC12ON = 0, REFON = 1, REF2_5V = 0	3 V		0.5	0.8	mA
C _I †	Input capacitance	Only one terminal can be selected at one time, P6.x/Ax	2.2 V			40	pF
R _I †	Input MUX ON resistance	$0V \le V_{AX} \le V_{AVCC}$	3 V			2000	Ω

[†] Not production tested, limits verified by design

NOTES: 1. The leakage current is defined in the leakage current table with P6.x/Ax parameter.

- 2. The analog input voltage range must be within the selected reference voltage range V_{R+} to V_{R-} for valid conversion results.
- 3. The internal reference supply current is not included in current consumption parameter IADC12.
- 4. The internal reference current is supplied via terminal AVCC. Consumption is independent of the ADC12ON control bit, unless a conversion is active. The REFON bit enables to settle the built-in reference before starting an A/D conversion.

12-bit ADC, external reference (see Note 1)

PARAMETER		TEST CONDITIONS		MIN	NOM	MAX	UNIT
V _{eREF+}	Positive external reference voltage input	V _{eREF+} > V _{REF} _/V _{eREF} _ (see Note 2)		1.4		VAVCC	٧
VREF-/VeREF-	Negative external reference voltage input	VeREF+ > VREF_/VeREF_ (see Note 3)		0		1.2	٧
(VeREF+ - VREF-/VeREF-)	Differential external reference voltage input	VeREF+ > VREF_/VeREF_ (see Note 4)		1.4		VAVCC	V
I _{VeREF+}	Static input current	0V ≤V _{eREF+} ≤ V _{AVCC}	2.2 V/3 V			±1	μΑ
IVREF-/VeREF-	Static input current	0V ≤ V _{eREF} – ≤ V _{AVCC}	2.2 V/3 V		•	±1	μΑ

- NOTES: 1. The external reference is used during conversion to charge and discharge the capacitance array. The input capacitance, Ci, is also the dynamic load for an external reference during conversion. The dynamic impedance of the reference supply should follow the recommendations on analog-source impedance to allow the charge to settle for 12-bit accuracy.
 - 2. The accuracy limits the minimum positive external reference voltage. Lower reference voltage levels may be applied with reduced
 - 3. The accuracy limits the maximum negative external reference voltage. Higher reference voltage levels may be applied with reduced accuracy requirements.
 - 4. The accuracy limits minimum external differential reference voltage. Lower differential reference voltage levels may be applied with reduced accuracy requirements.



12-bit ADC, built-in reference

PARAMETER		TEST CONDITIONS		MIN	NOM	MAX	UNIT	
V _{REF+}	Positive built-in reference voltage output	REF2_5V = 1 for 2.5 V $ VREF_{+} \le VREF_{+} $ Max	3 V	2.4	2.5	2.6		
		REF2_5V = 0 for 1.5 V $ VREF_{+} \le VREF_{+} $ Max	2.2 V/3 V	1.44	1.5	1.56	V	
AV _{CC} (min)	AV _{CC} minimum voltage, Positive built-in reference active	REF2_5V = 0, I _{VREF+} ≤ 1mA		2.2				
		REF2_5V = 1, $I_{VREF+} \le 0.5 mA$		V _{REF+} + 0.15			V	
		REF2_5V = 1, I _{VREF+} ≤ 1mA		V _{REF+} + 0.15				
lvref+	Load current out of VREF+ terminal		2.2 V	0.01		-0.5	mA	
			3 V			-1		
^I L(VREF)+ [†]	Load-current regulation V _{REF+} terminal	I_{VREF+} = 500 μA +/- 100 μA Analog input voltage ~0.75 V; REF2_5V = 0	2.2 V			±2	LSB	
			3 V			±2		
		I_{VREF+} = 500 μA ± 100 μA Analog input voltage ~1.25 V; REF2_5V = 1	3 V			±2	LSB	
I _{DL(VREF)} + [‡]	Load current regulation V _{REF+} terminal	$\begin{split} & \text{IVREF+} = 100 \; \mu\text{A} \rightarrow 900 \; \mu\text{A}, \\ & \text{CVREF+} = 5 \; \mu\text{F}, \; \text{ax} \; \text{~0.5 x V}_{\text{REF+}} \\ & \text{Error of conversion result} \; \leq 1 \; \text{LSB} \end{split}$	3 V			20	ns	
C _{VREF+}	Capacitance at pin V _{REF+} (see Note 1)	REFON =1, 0 mA ≤ l _{VREF+} ≤ l _{VREF+} max	2.2 V/3 V	5	10		μF	
T _{REF+} †	Temperature coefficient of built-in reference	I_{VREF+} is a constant in the range of 0 mA $\leq I_{VREF+} \leq 1$ mA	2.2 V/3 V			±100	ppm/°C	
^t REFON [†]	Settle time of internal reference voltage (see Figure 13 and Note 2)	$I_{VREF+} = 0.5$ mA, $C_{VREF+} = 10$ μ F, $V_{REF+} = 1.5$ V, $V_{AVCC} = 2.2$ V				17	ms	

[†] Not production tested, limits characterized

NOTES: 1. The internal buffer operational amplifier and the accuracy specifications require an external capacitor. All INL and DNL tests uses two capacitors between pins V_{REF+} and AV_{SS} and V_{REF-}/V_{eREF-} and AV_{SS}: 10 μF tantalum and 100 nF ceramic.

NOTES: 2. The condition is that the error in a conversion started after t_{REFON} is less than ±0.5 LSB. The settling time depends on the external capacitive load.

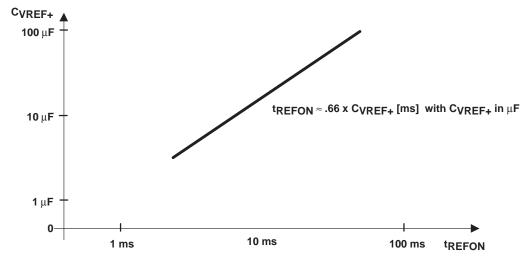


Figure 13. Typical Settling Time of Internal Reference $t_{\mbox{\scriptsize REFON}}$ vs External Capacitor on $V_{\mbox{\scriptsize REF}}$ +



[‡] Not production tested, limits verified by design

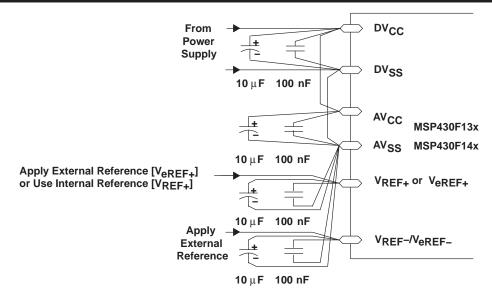


Figure 14. Supply Voltage and Reference Voltage Design V_{REF-}/V_{eREF-} External Supply

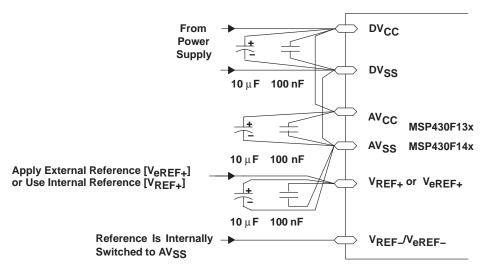


Figure 15. Supply Voltage and Reference Voltage Design V_{REF-}/V_{eREF-} = AV_{SS}, Internally Connected

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electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

12-bit ADC, timing parameters

P	ARAMETER	TEST CONDITIONS		MIN	NOM	MAX	UNIT
fADC12CLK		For specified performance of ADC12 linearity parameters	2.2V/ 3V	0.45	5	6.3	MHz
fADC12OSC	Internal ADC12 oscillator	ADC12DIV=0, fADC12CLK=fADC12OSC	2.2 V/ 3V	3.7		6.3	MHz
	Conversion time	$C_{VREF+} \ge 5 \mu F$, Internal oscillator, $f_{ADC12OSC} = 3.7 \text{ MHz}$ to 6.3 MHz	2.2 V/ 3 V	2.06		3.51	μs
^t CONVERT	Conversion time	External f _{ADC12CLK} from ACLK, MCLK or SADC12SSEL ≠ 0	SMCLK:		13×ADC12DIV× 1/fADC12CLK		μs
tADC12ON [‡]	Turn on settling time of the ADC	(see Note 1)				100	ns
. +	Committee time	$R_S = 400 \Omega, R_I = 1000 \Omega,$	3 V	1220			
^t Sample [‡]	Sampling time	$C_{I} = 30 \text{ pF}$ $\tau = [R_{S} + R_{I}] \times C_{I}; \text{(see Note 2)}$	2.2 V	1400			ns

[†] Not production tested, limits characterized

NOTES: 1. The condition is that the error in a conversion started after t_{ADC12ON} is less than ±0.5 LSB. The reference and input signal are already settled.

2. Approximately ten Tau (τ) are needed to get an error of less than ± 0.5 LSB: $t_{Sample} = ln(2^{n+1}) \times (R_S + R_I) \times C_I + 800$ ns where n = ADC resolution = 12, $R_S =$ external source resistance.

12-bit ADC, linearity parameters

	PARAMETER	TEST CONDITIONS		MIN	NOM	MAX	UNIT
_	lata and linearity amon	$1.4 \text{ V} \le (\text{V}_{\text{eREF+}} - \text{V}_{\text{REF-}}/\text{V}_{\text{eREF-}}) \text{ min} \le 1.6 \text{ V}$	0.0.1/0.1/			<u>+2</u>	1.00
ΕĮ	Integral linearity error	$1.6 \text{ V} < (\text{V}_{\text{eREF+}} - \text{V}_{\text{REF-}}/\text{V}_{\text{eREF-}}) \text{ min } \leq [\text{V}_{\text{(AVCC)}}]$	2.2 V/3 V			±1.7	LSB
ED	Differential linearity error	$ \begin{array}{l} (V_{\mbox{\footnotesize{eREF+}}}-V_{\mbox{\footnotesize{REF-}}})_{\mbox{\footnotesize{min}}} \leq (V_{\mbox{\footnotesize{eREF+}}}-V_{\mbox{\footnotesize{REF-}}}), \\ C_{\mbox{\footnotesize{VREF+}}} = 10~\mu F \mbox{\footnotesize{(tantalum)}} \mbox{\footnotesize{and}} \mbox{\footnotesize{100 nF}} \mbox{\footnotesize{(ceramic)}} \end{array} $	2.2 V/3 V			±1	LSB
EO	Offset error	$ \begin{array}{l} (V_{eREF+}-V_{REF-}\!$	2.2 V/3 V		±2	±4	LSB
EG	Gain error	$\begin{array}{l} (V_{eREF+}-V_{REF-}/V_{eREF-})_{min} \leq (V_{eREF+}-V_{REF-}/V_{eREF-}), \\ C_{VREF+} = 10~\mu F~(tantalum)~and~100~nF~(ceramic) \end{array}$	2.2 V/3 V		±1.1	±2	LSB
ET	Total unadjusted error	$\begin{array}{l} (V_{eREF+}-V_{REF-}/V_{eREF-})_{min} \leq (V_{eREF+}-V_{REF-}/V_{eREF-}), \\ C_{VREF+} = 10~\mu F~(tantalum)~and~100~nF~(ceramic) \end{array}$	2.2 V/3 V		±2	±5	LSB

[‡] Not production tested, limits verified by design

MSP430x13x, MSP430x14x, MSP430x14x1 MIXED SIGNAL MICROCONTROLLER

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electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

12-bit ADC, temperature sensor and built-in V_{MID}

	PARAMETER	TEST CONDITIONS		MIN	NOM	MAX	UNIT
	Operating supply current into	REFON = 0, INCH = 0Ah,	2.2 V		40	120	
ISENSOR	AV _{CC} terminal (see Note 1)	ADC12ON=NA, T _A = 25°C	3 V		60	160	μΑ
\/+		ADC12ON = 1, INCH = 0Ah,	2.2 V		986	986±5%	\/
VSENSOR [†]		$T_A = 0$ °C	3 V		986	986±5%	mV
TC		ADC400NL 4 INCLL 0AL	2.2 V		3.55	3.55±3%	>//00
TC _{SENSOR} †		ADC12ON = 1, INCH = 0Ah	3 V		3.55	3.55±3%	mV/°C
4	Sample time required if channel	ADC12ON = 1, INCH = 0Ah,	2.2 V	30			_
^t SENSOR(sample) [†]	10 is selected (see Note 2)	Error of conversion result ≤ 1 LSB	3 V	30			μs
	Current into divider at channel 11	ADOLOGNI A INICII ODI	2.2 V			NA	
IVMID	(see Note 3)	ADC12ON = 1, INCH = 0Bh	3 V			NA	μΑ
Maria	AV/ division at absence 44	ADC12ON = 1, INCH = 0Bh,	2.2 V		1.1	1.1±0.04	.,
VMID	AV _{CC} divider at channel 11	V _{MID} is ~0.5 x V _{AVCC}	3 V		1.5	1.50±0.04	V
	Sample time required if channel	ADC12ON = 1, INCH = 0Bh, 2		1400	•	·	20
tVMID(sample)	11 is selected (see Note 4)	Error of conversion result ≤ 1 LSB	3 V	1220	•	·	ns

[†] Not production tested, limits characterized

NOTES: 1. The sensor current I_{SENSOR} is consumed if (ADC12ON = 1 and REFON=1), or (ADC12ON=1 AND INCH=0Ah and sample signal is high). Therefore it includes the constant current through the sensor and the reference.

- 2. The typical equivalent impedance of the sensor is 51 k Ω . The sample time required includes the sensor-on time tSENSOR(on).
- 3. No additional current is needed. The $\mbox{\ensuremath{V_{\mbox{\footnotesize MID}}}}$ is used during sampling.
- 4. The on-time tymino(on) is included in the sampling time tymino(sample); no additional on time is needed.



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electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

Flash Memory

	PARAMETER	TEST CONDITIONS	VCC	MIN	NOM	MAX	UNIT
VCC(PGM/ ERASE)	Program and Erase supply voltage			2.7		3.6	٧
fFTG	Flash Timing Generator frequency			257		476	kHz
IPGM	Supply current from DV _{CC} during program		2.7 V/ 3.6 V		3	5	mA
IERASE	Supply current from DV _{CC} during erase		2.7 V/ 3.6 V		3	7	mA
^t CPT	Cumulative program time	see Note 1	2.7 V/ 3.6 V			4	ms
tCMErase	Cumulative mass erase time	see Note 2	2.7 V/ 3.6 V	200			ms
	Program/Erase endurance			10 ⁴	10 ⁵		cycles
^t Retention	Data retention duration	T _J = 25°C		100			years
^t Word	Word or byte program time				35		
^t Block, 0	Block program time for 1 St byte or word				30		
^t Block, 1-63	Block program time for each additional byte or word	and Nata O			21		
^t Block, End	Block program end-sequence wait time	see Note 3			6		tFTG
^t Mass Erase					5297		
tSeg Erase	Segment erase time				4819	·	

- NOTES: 1. The cumulative program time must not be exceeded when writing to a 64-byte flash block. This parameter applies to all programming methods: individual word/byte write and block write modes.
 - 2. The mass erase duration generated by the flash timing generator is at least 11.1ms (= 5297x1/f_{FTG},max = 5297x1/476kHz). To achieve the required cumulative mass erase time the Flash Controller's mass erase operation can be repeated until this time is met. (A worst case minimum of 19 cycles are required).
 - 3. These values are hardwired into the Flash Controller's state machine ($t_{FTG} = 1/f_{FTG}$).

JTAG Interface

	PARAMETER	TEST CONDITIONS	Vcc	MIN	NOM	MAX	UNIT
,	TOW's and for many	and Materia	2.2 V	0		5	MHz
TCK	TCK input frequency	see Note 1	3 V	0		10	MHz
R _{Internal}	Internal pull-up resistance on TMS, TCK, TDI/TCLK	see Note 2	2.2 V/ 3 V	25	60	90	kΩ

NOTES: 1. f_{TCK} may be restricted to meet the timing requirements of the module selected.

2. TMS, TDI/TCLK, and TCK pull-up resistors are implemented in all versions.

JTAG Fuse (see Note 1)

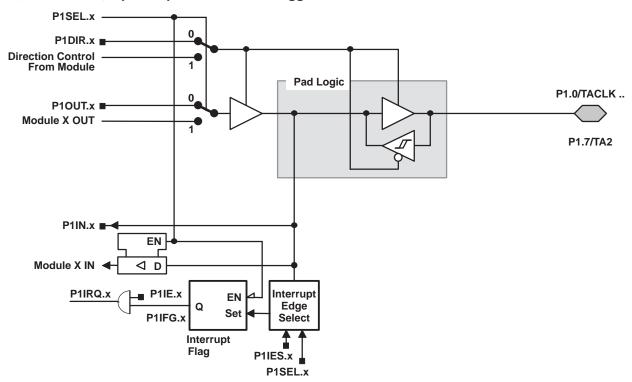
	PARAMETER	TEST CONDITIONS	vcc	MIN	NOM	MAX	UNIT
V _{CC(FB)}	Supply voltage during fuse-blow condition	T _A = 25°C		2.5			V
V_{FB}	Voltage level on TDI/TCLK for fuse-blow: F versions			6		7	V
I _{FB}	Supply current into TDI/TCLK during fuse blow					100	mA
t _{FB}	Time to blow fuse					1	ms

NOTES: 1. Once the fuse is blown, no further access to the MSP430 JTAG/Test and emulation features is possible. The JTAG block is switched to bypass mode.



input/output schematic

port P1, P1.0 to P1.7, input/output with Schmitt-trigger



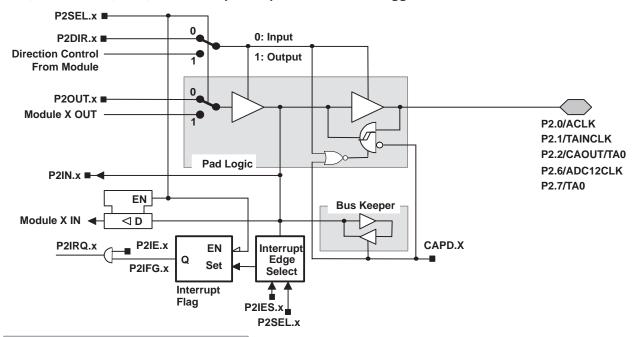
PnSel.x	PnDIR.x	Dir. CONTROL FROM MODULE	PnOUT.x	MODULE X OUT	PnIN.x	MODULE X IN	PnIE.x	PnIFG.x	PnIES.x
P1Sel.0	P1DIR.0	P1DIR.0	P1OUT.0	DVSS	P1IN.0	TACLK [†]	P1IE.0	P1IFG.0	P1IES.0
P1Sel.1	P1DIR.1	P1DIR.1	P1OUT.1	Out0 signal [†]	P1IN.1	CCI0A†	P1IE.1	P1IFG.1	P1IES.1
P1Sel.2	P1DIR.2	P1DIR.2	P1OUT.2	Out1 signal [†]	P1IN.2	CCI1A [†]	P1IE.2	P1IFG.2	P1IES.2
P1Sel.3	P1DIR.3	P1DIR.3	P1OUT.3	Out2 signal [†]	P1IN.3	CCI2A†	P1IE.3	P1IFG.3	P1IES.3
P1Sel.4	P1DIR.4	P1DIR.4	P1OUT.4	SMCLK	P1IN.4	unused	P1IE.4	P1IFG.4	P1IES.4
P1Sel.5	P1DIR.5	P1DIR.5	P1OUT.5	Out0 signal [†]	P1IN.5	unused	P1IE.5	P1IFG.5	P1IES.5
P1Sel.6	P1DIR.6	P1DIR.6	P1OUT.6	Out1 signal [†]	P1IN.6	unused	P1IE.6	P1IFG.6	P1IES.6
P1Sel.7	P1DIR.7	P1DIR.7	P1OUT.7	Out2 signal [†]	P1IN.7	unused	P1IE.7	P1IFG.7	P1IES.7

[†] Signal from or to Timer_A



input/output schematic (continued)

port P2, P2.0 to P2.2, P2.6, and P2.7 input/output with Schmitt-trigger



x: Bit Identifier 0 to 2, 6, and 7 for Port P2

PnSel.x	PnDIR.x	Dir. CONTROL FROM MODULE	PnOUT.x	MODULE X OUT	PnIN.x	MODULE X IN	PnIE.x	PnIFG.x	PnIES.x
P2Sel.0	P2DIR.0	P2DIR.0	P2OUT.0	ACLK	P2IN.0	unused	P2IE.0	P2IFG.0	P2IES.0
P2Sel.1	P2DIR.1	P2DIR.1	P2OUT.1	DV _{SS}	P2IN.1	INCLK‡	P2IE.1	P2IFG.1	P2IES.1
P2Sel.2	P2DIR.2	P2DIR.2	P2OUT.2	CAOUT	P2IN.2	CCI0B‡	P2IE.2	P2IFG.2	P2IES.2
P2Sel.6	P2DIR.6	P2DIR.6	P2OUT.6	ADC12CLK¶	P2IN.6	unused	P2IE.6	P2IFG.6	P2IES.6
P2Sel.7	P2DIR.7	P2DIR.7	P2OUT.7	Out0 signal§	P2IN.7	unused	P2IE.7	P2IFG.7	P2IES.7

[†] Signal from Comparator_A

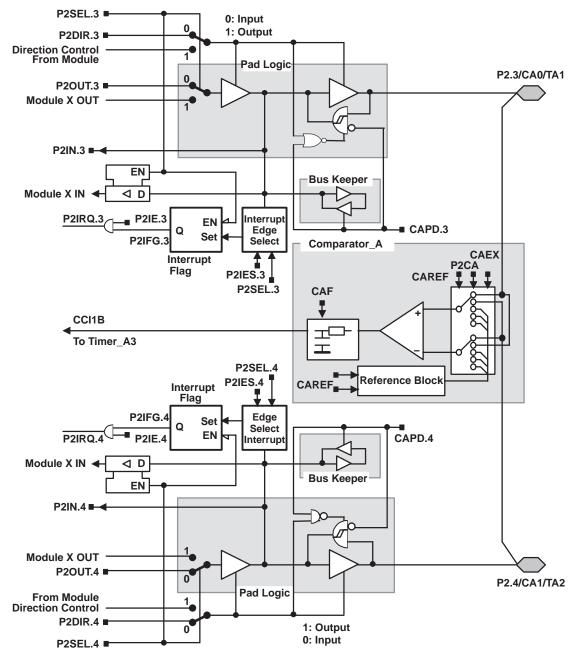
[‡] Signal to Timer_A

[§] Signal from Timer_A

[¶] ADC12CLK signal is output of the 12-bit ADC module

input/output schematic (continued)

port P2, P2.3 to P2.4, input/output with Schmitt-trigger



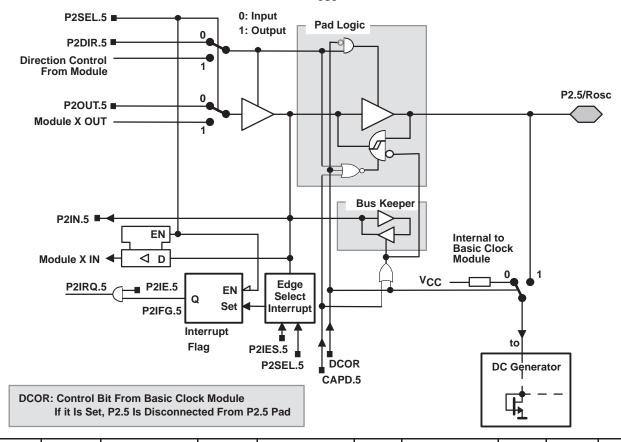
PnSel.x	PnDIR.x	DIRECTION CONTROL FROM MODULE	PnOUT.x	MODULE X OUT	PnIN.x	MODULE X IN	PnIE.x	PnIFG.x	PnIES.x
P2Sel.3	P2DIR.3	P2DIR.3	P2OUT.3	Out1 signal [†]	P2IN.3	unused	P2IE.3	P2IFG.3	P2IES.3
P2Sel.4	P2DIR.4	P2DIR.4	P2OUT.4	Out2 signal [†]	P2IN.4	unused	P2IE.4	P2IFG.4	P2IES.4

[†] Signal from Timer_A



input/output schematic (continued)

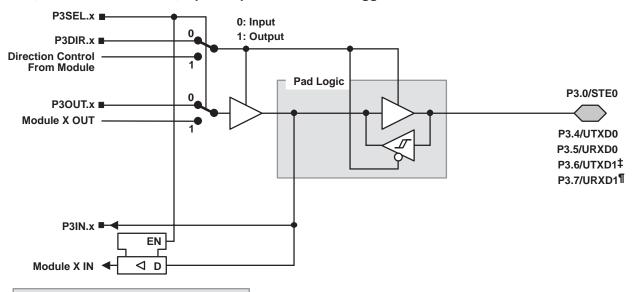
port P2, P2.5, input/output with Schmitt-trigger and R_{osc} function for the basic clock module



PnSel.x	PnDIR.x	DIRECTION CONTROL FROM MODULE	PnOUT.x	MODULE X OUT	PnIN.x	MODULE X IN	PnIE.x	PnIFG.x	PnIES.x
P2Sel.5	P2DIR.5	P2DIR.5	P2OUT.5	DVSS	P2IN.5	unused	P2IE.5	P2IFG.5	P2IES.5

input/output schematic (continued)

port P3, P3.0 and P3.4 to P3.7, input/output with Schmitt-trigger



x: Bit Identifier, 0 and 4 to 7 for Port P3

PnSel.x	PnDIR.x	DIRECTION CONTROL FROM MODULE	PnOUT.x	MODULE X OUT	PnIN.x	MODULE X IN
P3Sel.0	P3DIR.0	DV _{SS}	P3OUT.0	DV _{SS}	P3IN.0	STE0
P3Sel.4	P3DIR.4	DV _{CC}	P3OUT.4	UTXD0 [†]	P3IN.4	Unused
P3Sel.5	P3DIR.5	DVSS	P3OUT.5	DVSS	P3IN.5	URXD0§
P3Sel.6	P3DIR.6	DV _{CC}	P3OUT.6	UTXD1 [‡]	P3IN.6	Unused
P3Sel.7	P3DIR.7	DVSS	P3OUT.7	DVSS	P3IN.7	URXD1¶

[†] Output from USART0 module

[‡] Output from USART1 module in x14x(1) configuration, DV_{SS} in x13x configuration

[§] Input to USART0 module

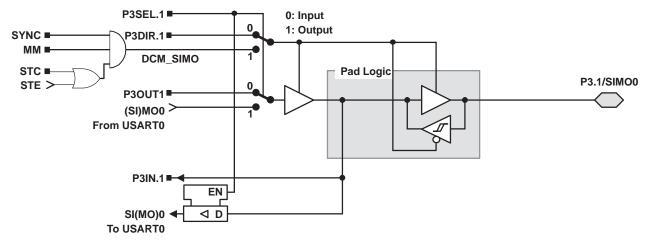
[¶] Input to USART1 module in x14x(1) configuration, unused in x13x configuration

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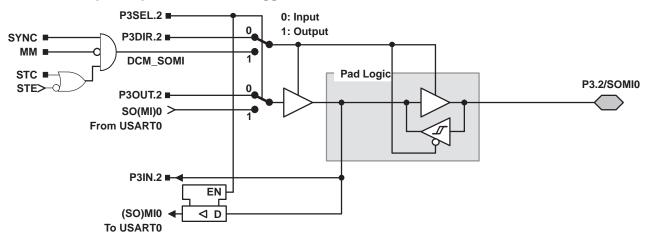
APPLICATION INFORMATION

input/output schematic (continued)

port P3, P3.1, input/output with Schmitt-trigger

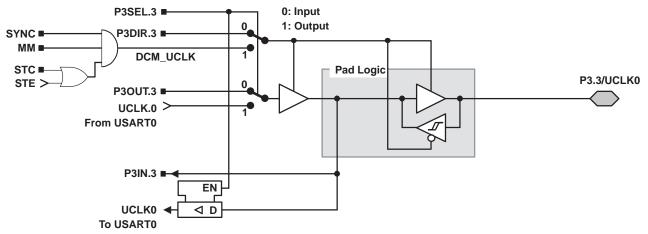


port P3, P3.2, input/output with Schmitt-trigger



input/output schematic (continued)

port P3, P3.3, input/output with Schmitt-trigger



NOTE: UART mode: The UART clock can only be an input. If UART mode and UART function are selected, the P3.3/UCLK0 is always

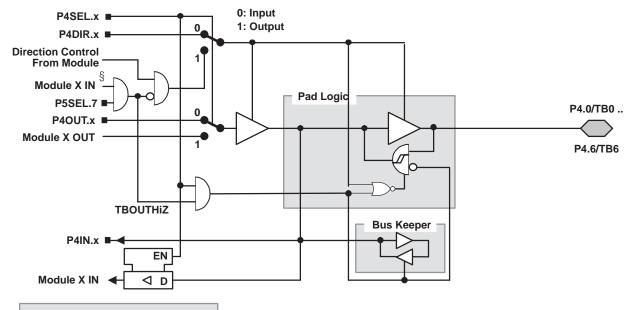
an input.

SPI, slave mode: The clock applied to UCLK0 is used to shift data in and out.

SPI, master mode: The clock to shift data in and out is supplied to connected devices on pin P3.3/UCLK0 (in slave mode).

input/output schematic (continued)

port P4, P4.0 to P4.6, input/output with Schmitt-trigger



x: bit identifier, 0 to 6 for Port P4

PnSel.x	PnDIR.x	DIRECTION CONTROL FROM MODULE	PnOUT.x	MODULE X OUT	PnIN.x	MODULE X IN
P4Sel.0	P4DIR.0	P4DIR.0	P4OUT.0	Out0 signal [†]	P4IN.0	CCI0A / CCI0B [‡]
P4Sel.1	P4DIR.1	P4DIR.1	P4OUT.1	Out1 signal [†]	P4IN.1	CCI1A / CCI1B‡
P4Sel.2	P4DIR.2	P4DIR.2	P4OUT.2	Out2 signal [†]	P4IN.2	CCI2A / CCI2B‡
P4Sel.3	P4DIR.3	P4DIR.3	P4OUT.3	Out3 signal†	P4IN.3	CCI3A / CCI3B‡
P4Sel.4	P4DIR.4	P4DIR.4	P4OUT.4	Out4 signal†	P4IN.4	CCI4A / CCI4B‡
P4Sel.5	P4DIR.5	P4DIR.5	P4OUT.5	Out5 signal†	P4IN.5	CCI5A / CCI5B‡
P4Sel.6	P4DIR.6	P4DIR.6	P4OUT.6	Out6 signal [†]	P4IN.6	CCI6A [‡]

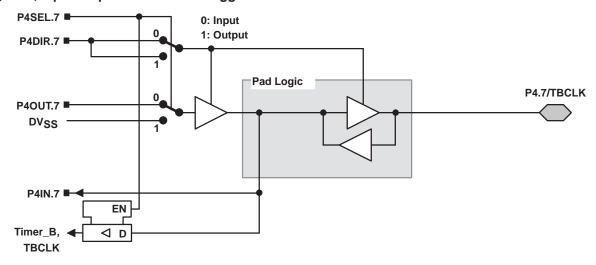
[†] Signal from Timer_B

[‡] Signal to Timer_B

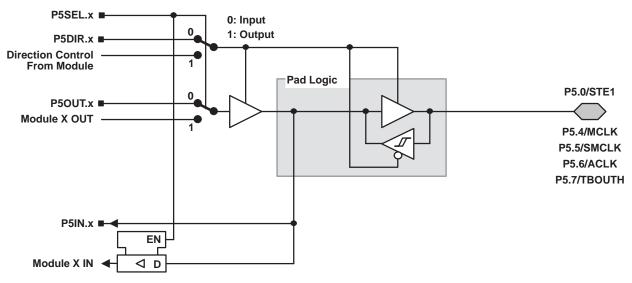
[§] From P5.7

input/output schematic (continued)

port P4, P4.7, input/output with Schmitt-trigger



port P5, P5.0 and P5.4 to P5.7, input/output with Schmitt-trigger



x: Bit Identifier, 0 and 4 to 7 for Port P5

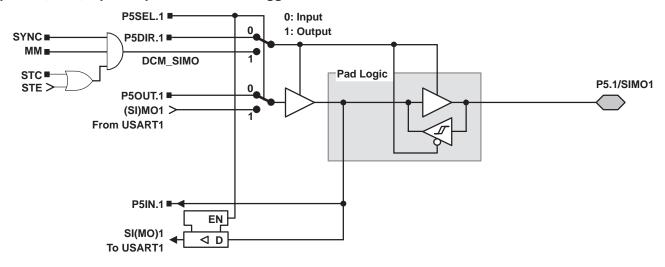
PnSel.x	PnDIR.x	Dir. CONTROL FROM MODULE	PnOUT.x	MODULE X OUT	PnIN.x	MODULE X IN
P5Sel.0	P5DIR.0	DV _{SS}	P5OUT.0	DV _{SS}	P5IN.0	STE.1
P5Sel.4	P5DIR.4	DVCC	P5OUT.4	MCLK	P5IN.4	unused
P5Sel.5	P5DIR.5	DVCC	P5OUT.5	SMCLK	P5IN.5	unused
P5Sel.6	P5DIR.6	DVCC	P5OUT.6	ACLK	P5IN.6	unused
P5Sel.7	P5DIR.7	DV _{SS}	P5OUT.7	DV _{SS}	P5IN.7	TBOUTHiZ

NOTE: TBOUTHiZ signal is used by port module P4, pins P4.0 to P4.6. The function of TBOUTHiZ is mainly useful when used with Timer_B7.

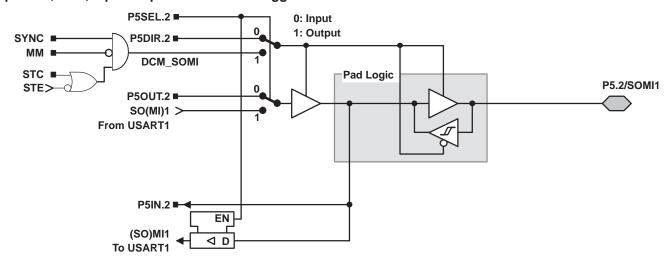


input/output schematic (continued)

port P5, P5.1, input/output with Schmitt-trigger

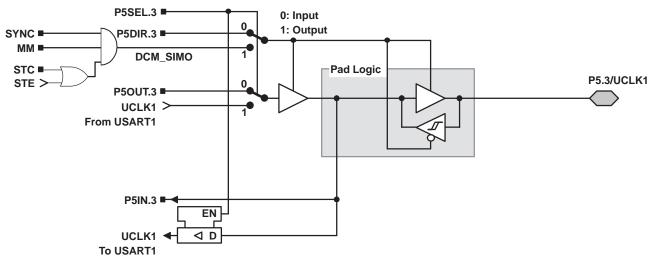


port P5, P5.2, input/output with Schmitt-trigger



input/output schematic (continued)

port P5, P5.3, input/output with Schmitt-trigger



NOTE: UART mode: The UART clock can only be an input. If UART mode and UART function are selected, the P5.3/UCLK1 direction

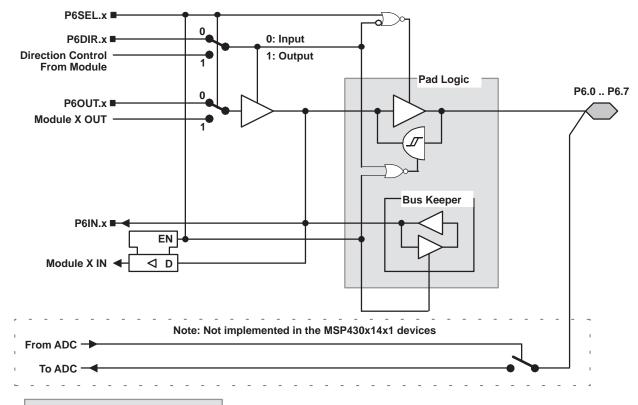
is always input.

SPI, slave mode: The clock applied to UCLK1 is used to shift data in and out.

SPI, master mode: The clock to shift data in and out is supplied to connected devices on pin P5.3/UCLK1 (in slave mode).

input/output schematic (continued)

port P6, P6.0 to P6.7, input/output with Schmitt-trigger



x: Bit Identifier, 0 to 7 for Port P6

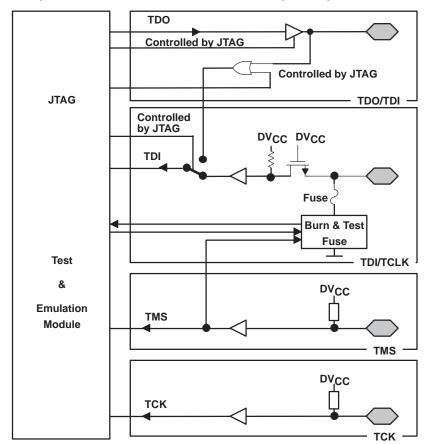
NOTE: Analog signals applied to digital gates can cause current flow from the positive to the negative terminal. The throughput current flows if the analog signal is in the range of transitions 0→1 or 1→0. The value of the throughput current depends on the driving capability of the gate. For MSP430, it is approximately 100 μA.

Use P6SEL.x=1 to prevent throughput current. P6SEL.x should be set, even if the signal at the pin is not being used by the ADC12.

PnSel.x	PnDIR.x	DIR. CONTROL FROM MODULE	PnOUT.x	MODULE X OUT	PnIN.x	MODULE X IN
P6Sel.0	P6DIR.0	P6DIR.0	P6OUT.0	DVSS	P6IN.0	unused
P6Sel.1	P6DIR.1	P6DIR.1	P6OUT.1	DVSS	P6IN.1	unused
P6Sel.2	P6DIR.2	P6DIR.2	P6OUT.2	DVSS	P6IN.2	unused
P6Sel.3	P6DIR.3	P6DIR.3	P6OUT.3	DV _{SS}	P6IN.3	unused
P6Sel.4	P6DIR.4	P6DIR.4	P6OUT.4	DV _{SS}	P6IN.4	unused
P6Sel.5	P6DIR.5	P6DIR.5	P6OUT.5	DVSS	P6IN.5	unused
P6Sel.6	P6DIR.6	P6DIR.6	P6OUT.6	DVSS	P6IN.6	unused
P6Sel.7	P6DIR.7	P6DIR.7	P6OUT.7	DVSS	P6IN.7	unused

NOTE: The signal at pins P6.x/Ax is used by the 12-bit ADC module.

JTAG pins TMS, TCK, TDI/TCLK, TDO/TDI, input/output with Schmitt-trigger



During Programming Activity and During Blowing of the Fuse, Pin TDO/TDI Is Used to Apply the Test Input Data for JTAG Circuitry

SLAS272F - JULY 2000 - REVISED JUNE 2004

APPLICATION INFORMATION

JTAG fuse check mode

MSP430 devices that have the fuse on the TDI/TCLK terminal have a fuse check mode that tests the continuity of the fuse the first time the JTAG port is accessed after a power-on reset (POR). When activated, a fuse check current, I_{TF}, of 1 mA at 3 V, 2.5 mA at 5 V can flow from the TDI/TCLK pin to ground if the fuse is not burned. Care must be taken to avoid accidentally activating the fuse check mode and increasing overall system power consumption.

Activation of the fuse check mode occurs with the first negative edge on the TMS pin after power up or if the TMS is being held low during power up. The second positive edge on the TMS pin deactivates the fuse check mode. After deactivation, the fuse check mode remains inactive until another POR occurs. After each POR the fuse check mode has the potential to be activated.

The fuse check current will only flow when the fuse check mode is active and the TMS pin is in a low state (see Figure 16). Therefore, the additional current flow can be prevented by holding the TMS pin high (default condition).

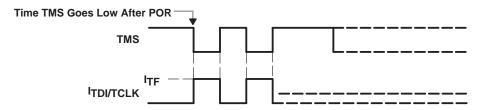


Figure 16. Fuse Check Mode Current: MSP430F13x, MSP430F14x(1)





10-Apr-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
MSP430F133IPAG	ACTIVE	TQFP	PAG	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR	-40 to 85	M430F133	Samples
MSP430F133IPM	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F133	Samples
MSP430F133IPMR	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F133	Samples
MSP430F133IRTDR	ACTIVE	VQFN	RTD	64	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F133	Samples
MSP430F133IRTDT	ACTIVE	VQFN	RTD	64	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F133	Samples
MSP430F135IPAG	ACTIVE	TQFP	PAG	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR	-40 to 85	M430F135 REV #	Samples
MSP430F135IPM	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F135 REV #	Samples
MSP430F135IPMR	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F135 REV #	Samples
MSP430F135IRTDR	ACTIVE	VQFN	RTD	64	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F135	Samples
MSP430F135IRTDT	ACTIVE	VQFN	RTD	64	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F135	Samples
MSP430F1471IPM	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F1471 REV #	Samples
MSP430F1471IPMR	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F1471 REV #	Samples
MSP430F1471IPMRG	ACTIVE	LQFP	PM	64		TBD	Call TI	Call TI	-40 to 85		Samples
MSP430F1471IRTDR	ACTIVE	VQFN	RTD	64	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F1471	Samples
MSP430F1471IRTDT	ACTIVE	VQFN	RTD	64	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F1471	Samples
MSP430F147IPAG	ACTIVE	TQFP	PAG	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR	-40 to 85	M430F147 REV #	Samples
MSP430F147IPM	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F147 REV #	Samples



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MSP430F147IPMR	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F147 REV #	Samples
MSP430F147IPMRG4	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F147 REV #	Samples
MSP430F147IRTDR	ACTIVE	VQFN	RTD	64	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F147	Samples
MSP430F147IRTDT	ACTIVE	VQFN	RTD	64	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F147	Samples
MSP430F1481IPM	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F1481	Samples
MSP430F1481IPMR	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F1481	Samples
MSP430F1481IRTDR	ACTIVE	VQFN	RTD	64	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F1481	Samples
MSP430F1481IRTDT	ACTIVE	VQFN	RTD	64	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F1481	Samples
MSP430F148IPAG	ACTIVE	TQFP	PAG	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR	-40 to 85	M430F148	Samples
MSP430F148IPM	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F148 REV #	Samples
MSP430F148IPMR	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F148 REV #	Samples
MSP430F148IRTDR	ACTIVE	VQFN	RTD	64	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F148	Samples
MSP430F148IRTDT	ACTIVE	VQFN	RTD	64	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F148	Samples
MSP430F1491IPM	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F1491	Samples
MSP430F1491IPMG4	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F1491	Samples
MSP430F1491IPMR	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F1491	Samples
MSP430F1491IPMRG4	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F1491	Samples
MSP430F1491IRTDR	ACTIVE	VQFN	RTD	64	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F1491	Samples



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PACKAGE OPTION ADDENDUM

10-Apr-2015

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MSP430F1491IRTDT	ACTIVE	VQFN	RTD	64	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F1491	Samples
MSP430F149IPAG	ACTIVE	TQFP	PAG	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR	-40 to 85	M430F149 REV #	Samples
MSP430F149IPAGR	ACTIVE	TQFP	PAG	64	1500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR	-40 to 85	M430F149 REV #	Samples
MSP430F149IPM	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F149 REV #	Samples
MSP430F149IPMG4	ACTIVE	LQFP	PM	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F149 REV #	Samples
MSP430F149IPMR	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F149 REV #	Samples
MSP430F149IPMRG4	ACTIVE	LQFP	PM	64	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	M430F149 REV #	Samples
MSP430F149IRTDR	ACTIVE	VQFN	RTD	64	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F149	Samples
MSP430F149IRTDT	ACTIVE	VQFN	RTD	64	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	M430F149	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

⁽³⁾ MSL. Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

10-Apr-2015

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO P1 BO W Cavity AO

	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



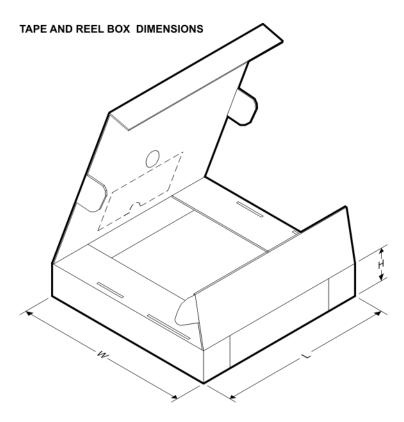
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MSP430F133IPMR	LQFP	PM	64	1000	330.0	24.4	13.0	13.0	2.1	16.0	24.0	Q2
MSP430F133IRTDR	VQFN	RTD	64	2500	330.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F133IRTDT	VQFN	RTD	64	250	180.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F135IPMR	LQFP	PM	64	1000	330.0	24.4	13.0	13.0	2.1	16.0	24.0	Q2
MSP430F135IRTDR	VQFN	RTD	64	2500	330.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F135IRTDT	VQFN	RTD	64	250	180.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F1471IPMR	LQFP	PM	64	1000	330.0	24.4	13.0	13.0	2.1	16.0	24.0	Q2
MSP430F1471IRTDR	VQFN	RTD	64	2500	330.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F1471IRTDT	VQFN	RTD	64	250	180.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F147IPMR	LQFP	PM	64	1000	330.0	24.4	13.0	13.0	2.1	16.0	24.0	Q2
MSP430F147IRTDR	VQFN	RTD	64	2500	330.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F147IRTDT	VQFN	RTD	64	250	180.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F1481IPMR	LQFP	PM	64	1000	330.0	24.4	13.0	13.0	2.1	16.0	24.0	Q2
MSP430F1481IRTDR	VQFN	RTD	64	2500	330.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F1481IRTDT	VQFN	RTD	64	250	180.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F148IPMR	LQFP	PM	64	1000	330.0	24.4	13.0	13.0	2.1	16.0	24.0	Q2
MSP430F148IRTDR	VQFN	RTD	64	2500	330.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F148IRTDT	VQFN	RTD	64	250	180.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2

PACKAGE MATERIALS INFORMATION

www.ti.com 19-Mar-2015

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MSP430F1491IPMR	LQFP	PM	64	1000	330.0	24.4	13.0	13.0	2.1	16.0	24.0	Q2
MSP430F1491IRTDR	VQFN	RTD	64	2500	330.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F1491IRTDT	VQFN	RTD	64	250	180.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F149IPAGR	TQFP	PAG	64	1500	330.0	24.4	13.0	13.0	1.5	16.0	24.0	Q2
MSP430F149IPMR	LQFP	PM	64	1000	330.0	24.4	13.0	13.0	2.1	16.0	24.0	Q2
MSP430F149IRTDR	VQFN	RTD	64	2500	330.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2
MSP430F149IRTDT	VQFN	RTD	64	250	180.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MSP430F133IPMR	LQFP	PM	64	1000	336.6	336.6	41.3
MSP430F133IRTDR	VQFN	RTD	64	2500	367.0	367.0	38.0
MSP430F133IRTDT	VQFN	RTD	64	250	210.0	185.0	35.0
MSP430F135IPMR	LQFP	PM	64	1000	336.6	336.6	41.3
MSP430F135IRTDR	VQFN	RTD	64	2500	367.0	367.0	38.0
MSP430F135IRTDT	VQFN	RTD	64	250	210.0	185.0	35.0
MSP430F1471IPMR	LQFP	PM	64	1000	336.6	336.6	41.3
MSP430F1471IRTDR	VQFN	RTD	64	2500	367.0	367.0	38.0
MSP430F1471IRTDT	VQFN	RTD	64	250	210.0	185.0	35.0
MSP430F147IPMR	LQFP	PM	64	1000	336.6	336.6	41.3



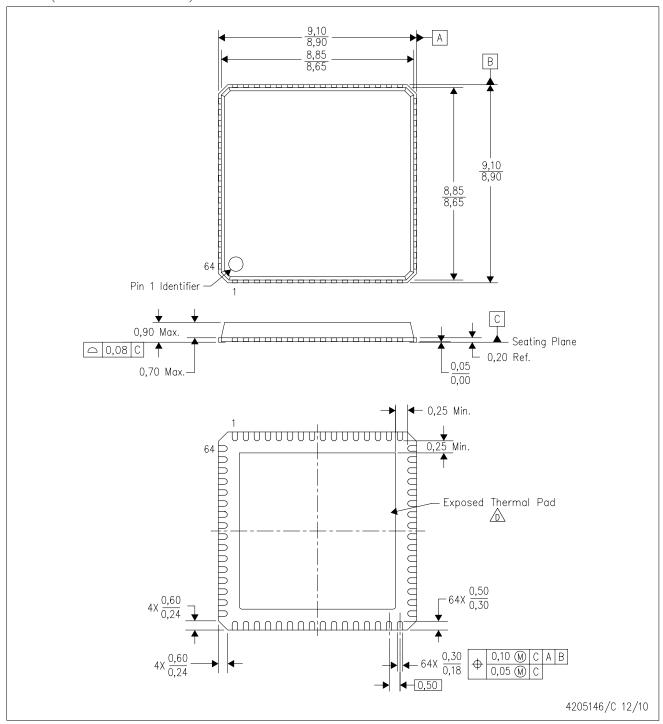
PACKAGE MATERIALS INFORMATION

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MSP430F147IRTDR	VQFN	RTD	64	2500	367.0	367.0	38.0
MSP430F147IRTDT	VQFN	RTD	64	250	210.0	185.0	35.0
MSP430F1481IPMR	LQFP	PM	64	1000	336.6	336.6	41.3
MSP430F1481IRTDR	VQFN	RTD	64	2500	367.0	367.0	38.0
MSP430F1481IRTDT	VQFN	RTD	64	250	210.0	185.0	35.0
MSP430F148IPMR	LQFP	PM	64	1000	336.6	336.6	41.3
MSP430F148IRTDR	VQFN	RTD	64	2500	367.0	367.0	38.0
MSP430F148IRTDT	VQFN	RTD	64	250	210.0	185.0	35.0
MSP430F1491IPMR	LQFP	PM	64	1000	336.6	336.6	41.3
MSP430F1491IRTDR	VQFN	RTD	64	2500	367.0	367.0	38.0
MSP430F1491IRTDT	VQFN	RTD	64	250	210.0	185.0	35.0
MSP430F149IPAGR	TQFP	PAG	64	1500	367.0	367.0	45.0
MSP430F149IPMR	LQFP	PM	64	1000	336.6	336.6	41.3
MSP430F149IRTDR	VQFN	RTD	64	2500	367.0	367.0	38.0
MSP430F149IRTDT	VQFN	RTD	64	250	210.0	185.0	35.0

RTD (S-PVQFN-N64)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) Package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.

 See the Product Data Sheet for details regarding the exposed thermal pad dimensions.



RTD (S-PVQFN-N64)

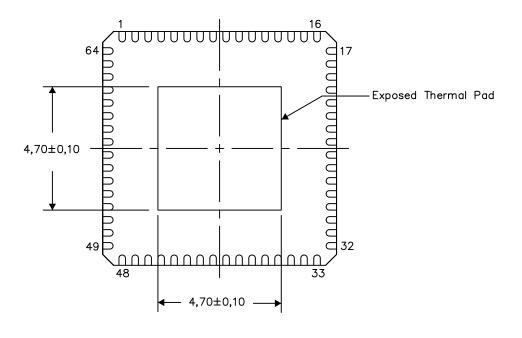
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

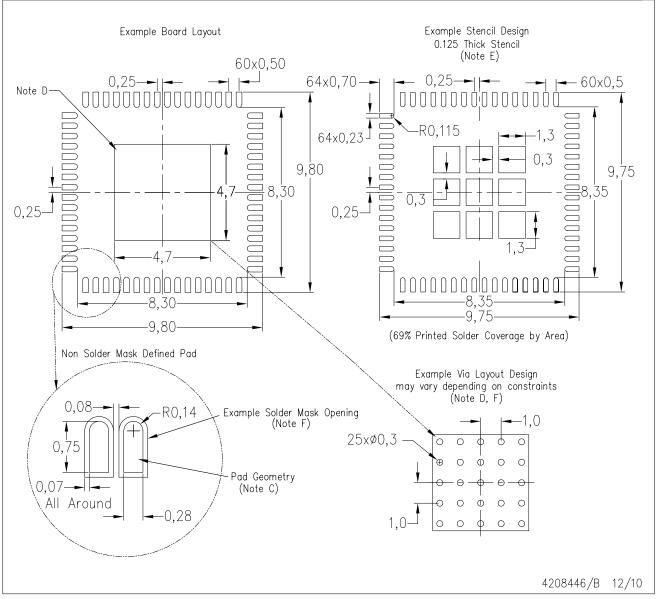
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NOTE: A. All linear dimensions are in millimeters



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PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Package, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com www.ti.com.
- E. Laser cutting apertures with electropolish and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customer should contact their board fabrication site for recommended solder mask tolerances and vias tenting recommendations for vias placed int the thermal pad.



PAG (S-PQFP-G64)

PLASTIC QUAD FLATPACK



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-026

PM (S-PQFP-G64)

PLASTIC QUAD FLATPACK

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NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-026
- D. May also be thermally enhanced plastic with leads connected to the die pads.

PM (S-PQFP-G64)

PLASTIC QUAD FLATPACK



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- D. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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